

# FCC LTE REPORT

## Certification

<b>Applicant Name:</b> SAMSUNG Electronics Co., Ltd.	<b>Date of Issue:</b> September 26, 2023
<b>Address:</b> 129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea	<b>Location:</b> HCT CO., LTD., 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, 17383, Rep. of KOREA
<b>Report No.:</b> HCT-RF-2309-FC019	

**FCC ID:** A3LSMA256U

**APPLICANT:** SAMSUNG Electronics Co., Ltd.

Model(s): SM-A256U  
 Additional Model(s): SM-A256U1/DS, SM-S256VL  
 EUT Type: Mobile phone  
 FCC Classification: PCS Licensed Transmitter Held to Ear (PCE)  
 FCC Rule Part(s): §27, §2

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	ERP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band12 (1.4)	699.7 – 715.3	1M10G7D	QPSK	0.062	17.89
		1M10W7D	16QAM	0.051	17.05
		1M10W7D	64QAM	0.040	16.03
		1M10W7D	256QAM	0.020	13.06
LTE – Band12 (3)	700.5 – 714.5	2M71G7D	QPSK	0.061	17.88
		2M70W7D	16QAM	0.051	17.09
		2M71W7D	64QAM	0.040	16.06
		2M71W7D	256QAM	0.020	13.09
LTE – Band12 (5)	701.5 – 713.5	4M51G7D	QPSK	0.061	17.88
		4M51W7D	16QAM	0.050	17.01
		4M51W7D	64QAM	0.040	16.06
		4M52W7D	256QAM	0.021	13.14
LTE – Band12 (10)	704.0 – 711.0	9M00G7D	QPSK	0.063	17.98
		9M01W7D	16QAM	0.051	17.08
		9M03W7D	64QAM	0.041	16.08
		8M98W7D	256QAM	0.021	13.23

The measurements shown in this report were made in accordance with the procedures specified in CFR47 section §2.947. I assume full responsibility for the accuracy and completeness of these measurements, and for the qualifications of all persons taking them.

HCT CO., LTD. Certifies that no party to this application has subject to a denial of Federal benefits that includes FCC benefits pursuant to section 5301 of the Anti-Drug Abuse Act of 1998, 21 U.S. C. 853(a)

Report No.: HCT-RF-2309-FC019

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REVIEWED BY



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Report prepared by : Jae Mun Do  
Engineer of Telecommunication Testing Center

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Report approved by : Jong Seok Lee  
Manager of Telecommunication Testing Center

The result shown in this test report refer only to the sample(s) tested unless otherwise stated.  
This test results were applied only to the test methods required by the standard.

This laboratory is not accredited for the test results marked \*.  
The above Test Report is the accredited test result by (KS Q) ISO/IEC 17025 and KOLAS(Korea Laboratory Accreditation Scheme), which signed the ILAC-MRA. (HCT Accreditation No.: KT197)

The report shall not be reproduced except in full(only partly) without approval of the laboratory.

## Version

TEST REPORT NO.	DATE	DESCRIPTION
HCT-RF-2309-FC019	September 26, 2023	- First Approval Report

The result shown in this test report refer only to the sample(s) tested unless otherwise stated.

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# MEASUREMENT REPORT

## 1. GENERAL INFORMATION

<b>Applicant Name:</b>	SAMSUNG Electronics Co., Ltd.
<b>Address:</b>	129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea
<b>FCC ID:</b>	A3LSMA256U
<b>Application Type:</b>	Certification
<b>FCC Classification:</b>	PCS Licensed Transmitter Held to Ear (PCE)
<b>FCC Rule Part(s):</b>	§27, §2
<b>EUT Type:</b>	Mobile phone
<b>Model(s):</b>	SM-A256U
<b>Additional Model(s):</b>	SM-A256U1/DS, SM-S256VL
<b>Tx Frequency:</b>	699.7 MHz – 715.3 MHz (LTE – Band 12 (1.4 MHz)) 700.5 MHz – 714.5 MHz (LTE – Band 12 (3 MHz)) 701.5 MHz – 713.5 MHz (LTE – Band 12 (5 MHz)) 704.0 MHz – 711.0 MHz (LTE – Band 12 (10 MHz))
<b>Date(s) of Tests:</b>	May 22, 2023 ~ September 04, 2023
<b>Serial number:</b>	Radiated: R3CW50MGDKF Conducted: 74530c3036337ece

## **2. INTRODUCTION**

### **2.1. DESCRIPTION OF EUT**

The EUT was a Mobile Phone with GSM/GPRS/EGPRS/UMTS and LTE, Sub6.

It also supports IEEE 802.11 a/b/g/n/ac (20/40/80 MHz), Bluetooth, BT LE, NFC.

### **2.2. MEASURING INSTRUMENT CALIBRATION**

The measuring equipment, which was utilized in performing the tests documented herein, has been calibrated in accordance with the manufacturer's recommendations for utilizing calibration equipment, which is traceable to recognized national standards.

### **2.3. TEST FACILITY**

The Fully-anechoic chamber and conducted measurement facility used to collect the radiated data are located at the **74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, 17383, Rep. of KOREA.**

### 3. DESCRIPTION OF TESTS

#### 3.1 TEST PROCEDURE

Test Description	Test Procedure Used
Occupied Bandwidth	- KDB 971168 D01 v03r01 – Section 4.3 - ANSI C63.26-2015 – Section 5.4.4
Band Edge	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Spurious and Harmonic Emissions at Antenna Terminal	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Conducted Output Power	- N/A (See SAR Report)
Frequency stability	- ANSI C63.26-2015 – Section 5.6
Effective Radiated Power/ Effective Isotropic Radiated Power	- KDB 971168 D01 v03r01 – Section 5.2 & 5.8 - ANSI/TIA-603-E-2016 – Section 2.2.17
Radiated Spurious and Harmonic Emissions	- KDB 971168 D01 v03r01 – Section 6.2 - ANSI/TIA-603-E-2016 – Section 2.2.12

## 3.2 RADIATED POWER

### Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

The equipment under test is placed on a non-conductive table 3-meters away from the receive antenna in accordance with ANSI/TIA-603-E-2016 Clause 2.2.17.

### Test Settings

1. Radiated power measurements are performed using the signal analyzer's "channel power" measurement capability for signals with continuous operation.
2. RBW = 1 – 5 % of the expected OBW, not to exceed 1 MHz
3. VBW  $\geq$  3 x RBW
4. Span = 1.5 times the OBW
5. No. of sweep points  $>$  2 x span / RBW
6. Detector = RMS
7. Trigger is set to "free run" for signals with continuous operation with the sweep times set to "auto".
8. The integration bandwidth was roughly set equal to the measured OBW of the signal for signals with continuous operation.
9. Trace mode = trace averaging (RMS) over 100 sweeps
10. The trace was allowed to stabilize

### Test Note

1. The turntable is rotated through 360 degrees, and the receiving antenna scans in order to determine the level of the maximized emission.
2. A half wave dipole is then substituted in place of the EUT. For emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The power is calculated by the following formula;

$$P_d \text{ (dBm)} = P_g \text{ (dBm)} - \text{cable loss (dB)} + \text{antenna gain (dB)}$$

Where:  $P_d$  is the dipole equivalent power and  $P_g$  is the generator output power into the substitution antenna.

3. The maximum value is calculated by adding the forward power to the calibrated source plus its appropriate gain value. These steps are repeated with the receiving antenna in both vertical and horizontal polarization. the difference

between the gain of the horn and an isotropic antenna are taken into consideration

4. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
5. All measurements are performed as RMS average measurements while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies.



### 3.3 RADIATED SPURIOUS EMISSIONS

#### Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

Radiated Spurious Emission Measurements at 3 meters by Substitution Method according to ANSI/TIA-603-E-2016.

#### Test Settings

1. RBW = 100 kHz for emissions below 1 GHz and 1 MHz for emissions above 1 GHz
2. VBW  $\geq 3 \times$  RBW
3. Span = 1.5 times the OBW
4. No. of sweep points  $> 2 \times$  span / RBW
5. Detector = Peak
6. Trace mode = Max Hold
7. The trace was allowed to stabilize
8. Test channel : Low/ Middle/ High
9. Frequency range : We are performed all frequency to 10<sup>th</sup> harmonics from 9 kHz.

#### Test Note

1. Measurements value show only up to 3 maximum emissions noted, or would be lesser if no specific emissions from the EUT are recorded (ie: margin  $> 20$  dB from the applicable limit) and considered that's already beyond the background noise floor.
2. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning. The worst case emissions are reported with the EUT positioning, modulations, RB sizes and offsets, and channel bandwidth configurations shown in the test data
3. For spurious emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The spurious emissions is calculated by the following formula;

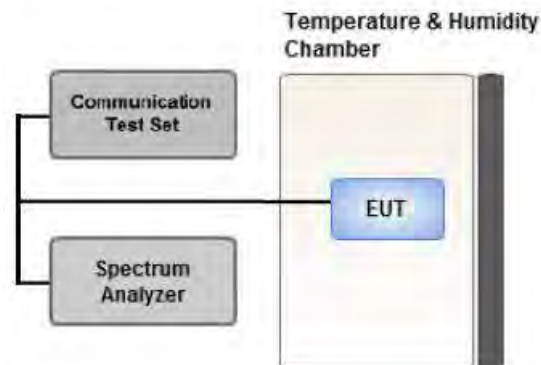
$$\text{Result}_{(dBm)} = P_g_{(dBm)} - \text{cable loss}_{(dB)} + \text{antenna gain}_{(dBi)}$$

Where:  $P_g$  is the generator output power into the substitution antenna.

If the fundamental frequency is below 1 GHz, RF output power has been converted to EIRP.

$$\text{EIRP}_{(dBm)} = \text{ERP}_{(dBm)} + 2.15$$

### 3.4 OCCUPIED BANDWIDTH.



#### Test setup

The width of a frequency band such that, below the lower and above the upper frequency limits, the mean powers emitted are each equal to a specified percentage 0.5 % of the total mean power of a given emission.

The EUT makes a call to the communication simulator.

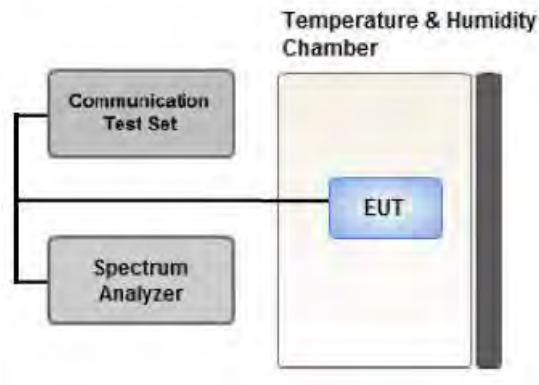
The conducted occupied bandwidth used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency. Use OBW measurement function of Spectrum analyzer to measure 99 % occupied bandwidth

#### Test Settings

1. The signal analyzer's automatic bandwidth measurement capability was used to perform the 99 % occupied bandwidth and the 26 dB bandwidth. The bandwidth measurement was not influenced by any intermediate power nulls in the fundamental emission.
2. RBW = 1 – 5 % of the expected OBW
3. VBW  $\geq 3 \times$  RBW
4. Detector = Peak
5. Trace mode = max hold
6. Sweep = auto couple
7. The trace was allowed to stabilize
8. If necessary, steps 2 – 7 were repeated after changing the RBW such that it would be within 1 – 5 % of the 99 % occupied bandwidth observed in Step 7

### 3.5 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL



**Test setup**

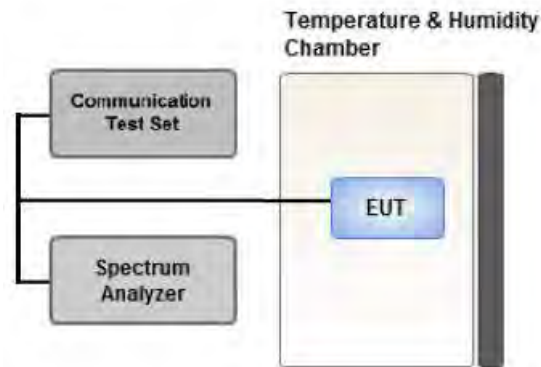
#### **Test Overview**

The level of the carrier and the various conducted spurious and harmonic frequencies is measured by means of a calibrated spectrum analyzer. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

#### **Test Settings**

1. RBW = 1 MHz
2. VBW  $\geq$  3 MHz
3. Detector = RMS
4. Trace Mode = trace average
5. Sweep time = auto
6. Number of points in sweep  $\geq$  2 \* Span / RBW

### 3.6 BAND EDGE



#### Test setup

##### Test Overview

All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

##### Test Settings

1. Start and stop frequency were set such that the band edge would be placed in the center of the plot
2. Span was set large enough so as to capture all out of band emissions near the band edge
3. RBW > 1 % of the emission bandwidth
4. VBW > 3 x RBW
5. Detector = RMS
6. Number of sweep points  $\geq 2 \times \text{Span/RBW}$
7. Trace mode = trace average
8. Sweep time = auto couple
9. The trace was allowed to stabilize

##### Test Notes

According to FCC 22.917, 24.238, 27.53 specified that power of any emission outside of The authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least  $43 + 10 \log(P)$  dB.

Compliance with this provision is based on the use of measurement instrumentation employing a resolution bandwidth of 100 kilohertz or greater.

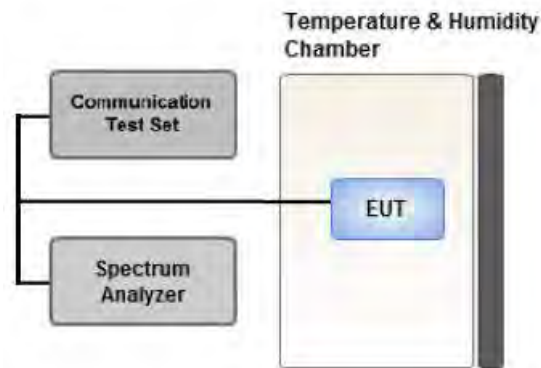
However, in the 100 kilohertz bands immediately outside and adjacent to a licensee's frequency block, a resolution bandwidth of at least 30 kHz may be employed.

All measurements were done at 2 channels(low and high operational frequency range.)

The band edge measurement used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

Where Margin < 1 dB the emission level is either corrected by  $10 \log(1 \text{ MHz/ RB})$  or the emission is integrated over a 1 MHz bandwidth to determine the final result. When using the integration method the integration window is either centered on the emission or, for emissions at the band edge, centered by an offset of 500 kHz from the block edge so that the integration window is the 1 MHz adjacent to the block edge.

### 3.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE



**Test setup**

#### **Test Overview**

Frequency stability testing is performed in accordance with the guidelines of ANSI C63.26-2015.

The frequency stability of the transmitter is measured by:

1. Temperature:

The temperature is varied from -30 °C to +50 °C in 10 °C increments using an environmental chamber.

2. Primary Supply Voltage:

- Unless otherwise specified, vary primary supply voltage from 85 % to 115 % of the nominal value for other than hand carried battery equipment.
- For hand carried, battery powered equipment, reduce the primary ac or dc supply voltage to the battery operating end point, which shall be specified by the manufacturer.

#### **Test Settings**

1. The carrier frequency of the transmitter is measured at room temperature (20 °C to provide a reference).
2. The equipment is turned on in a "standby" condition for fifteen minutes before applying power to the transmitter. Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.
3. Frequency measurements are made at 10 °C intervals ranging from -30 °C to +50 °C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

**3.8 WORST CASE(RADIATED TEST)**

- The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
- All modes of operation were investigated and the worst case configuration results are reported.  
 Mode : Stand alone, Stand alone + External accessories (Earphone, AC adapter, etc)  
 Worst case : Stand alone
- We were performed the RSE test in condition of co-location.  
 Mode : Stand alone, Simultaneous transmission scenarios  
 Worst case : Stand alone
- In the case of radiated spurious emissions, all bandwidth of operation were investigated and the worst case bandwidth results are reported. (Worst case : 10 MHz)
- The worst case is reported with the EUT positioning, modulations, and paging service configurations shown in the test data.
- Please refer to the table below.
- SM-A256U & additional models were tested and the worst case results are reported.  
 (Worst case : SM-A256U)

[ Worst case ]

Test Description	Modulation	Bandwidth (MHz)	Frequency	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	1.4	Low	1	0	Y
			Mid, High	1	5	
		3	Low	1	0	
			Mid, High	1	14	
		5	Low	1	0	
			Mid, High	1	24	
		10	Low	1	0	
			Mid, High	1	49	
Radiated Spurious and Harmonic Emissions	QPSK	10	Low	1	0	Y
			Mid, High	1	49	

**3.9 WORST CASE(CONDUCTED TEST)**

- All modes of operation were investigated and the worst case configuration results are reported.
- SM-A256U & additional models were tested and the worst case results are reported.  
(Worst case : SM-A256U)

[ Worst case ]

Test Description	Modulation	Bandwidth (MHz)	Frequency	RB size	RB offset
<b>Occupied Bandwidth</b>	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10	Mid	Full RB	0
<b>Band Edge</b>	QPSK	1.4	Low	1	0
			High	1	5
		3	Low	1	0
			High	1	14
		5	Low	1	0
			High	1	24
		10	Low	1	0
			High	1	49
1.4, 3, 5, 10	Low, High	Full RB	0		
	<b>Spurious and Harmonic Emissions at Antenna Terminal</b>	QPSK	1.4, 3, 5, 10	Low, Mid, High	1

#### 4. LIST OF TEST EQUIPMENT

Equipment	Model	Manufacturer	Serial No.	Due to Calibration	Calibration Interval
RF Switching System	FBSR-02B(1.2G HPF+LNA)	T&M SYSTEM	F1L1	01/19/2024	Annual
RF Switching System	FBSR-02B(3.3G HPF+LNA)	T&M SYSTEM	F1L2	01/19/2024	Annual
Power Splitter(DC ~ 26.5 GHz)	11667B	Hewlett Packard	5001	04/19/2024	Annual
DC Power Supply	E3632A	Agilent	MY40010147	06/23/2024	Annual
Dipole Antenna	UHAP	Schwarzbeck	557	03/09/2025	Biennial
Dipole Antenna	UHAP	Schwarzbeck	558	03/09/2025	Biennial
Chamber	SU-642	ESPEC	93008124	02/22/2024	Annual
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	147	08/17/2025	Biennial
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	9120D-1298	09/15/2023	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170342	09/29/2024	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170124	03/28/2025	Biennial
Signal Analyzer(10 Hz ~ 26.5 GHz)	N9020A	Agilent	MY52090906	04/20/2024	Annual
ATTENUATOR(20 dB)	8493C	Hewlett Packard	17280	04/19/2024	Annual
Spectrum Analyzer(10 Hz ~ 40 GHz)	FSV40	REOHDE & SCHWARZ	100931	08/17/2024	Annual
Base Station	8960 (E5515C)	Agilent	MY48360800	08/10/2024	Annual
Loop Antenna(9 kHz ~ 30 MHz)	FMZB1513	Schwarzbeck	1513-333	03/17/2024	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	895	08/16/2024	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	1135	03/21/2024	Biennial
Wideband Radio Communication Tester	MT8821C	Anritsu Corp.	6262094331	12/01/2023	Annual
Wideband Radio Communication Tester	MT8820C	Anritsu Corp.	6201026545	01/05/2024	Annual
SIGNAL GENERATOR (100 kHz ~ 40 GHz)	SMB100A	REOHDE & SCHWARZ	177633	06/22/2024	Annual
Signal Analyzer(5 Hz ~ 40.0 GHz)	N9030B	KEYSIGHT	MY55480167	05/24/2024	Annual
FCC LTE Mobile Conducted RF Automation Test Software	-	HCT CO., LTD.,	-	-	-

**Note:**

1. Equipment listed above that has a calibration due date during the testing period, the testing is completed before equipment expiration date.
2. Especially, all antenna for measurement is calibrated in accordance with the requirements of C63.5 (Version : 2017).



## 5. MEASUREMENT UNCERTAINTY

The measurement uncertainties shown below were calculated in accordance with the requirements of ANSI C63.4:2014. All measurement uncertainty values are shown with a coverage factor of  $k = 2$  to indicate a 95 % level of confidence. The measurement data shown herein meets or exceeds the  $U_{\text{CISPR}}$  measurement uncertainty values specified in CISPR 16-4-2 and, thus, can be compared directly to specified limits to determine compliance.

Parameter	Expanded Uncertainty ( $\pm$ dB)
Conducted Disturbance (150 kHz ~ 30 MHz)	1.90 (Confidence level about 95 %, $k=2$ )
Radiated Disturbance (9 kHz ~ 30 MHz)	4.14 (Confidence level about 95 %, $k=2$ )
Radiated Disturbance (30 MHz ~ 1 GHz)	5.16 (Confidence level about 95 %, $k=2$ )
Radiated Disturbance (1 GHz ~ 18 GHz)	5.57 (Confidence level about 95 %, $k=2$ )
Radiated Disturbance (18 GHz ~ 40 GHz)	5.76 (Confidence level about 95 %, $k=2$ )
Radiated Disturbance (Above 40 GHz)	5.52 (Confidence level about 95 %, $k=2$ )

## 6. SUMMARY OF TEST RESULTS

### 6.1 Test Condition : Conducted Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Occupied Bandwidth	§2.1049	N/A	PASS
Band Edge / Spurious and Harmonic Emissions at Antenna Terminal.	§2.1051, §27.53(g)	< 43 + 10log10 (P[Watts]) at Band Edge and for all out-of-band emissions	PASS
Conducted Output Power	§2.1046	N/A	<u>See Note1</u>
Frequency stability / variation of ambient temperature	§2.1055, §27.54	Emission must remain in band	PASS

Note:

1. See SAR Report

### 6.2 Test Condition : Radiated Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Effective Radiated Power	§27.50(c)(10)	< 3 Watts max. ERP	PASS
Radiated Spurious and Harmonic Emissions	§2.1053, §27.53(g)	< 43 + 10log10 (P[Watts]) for all out-of band emissions	PASS

## 7. SAMPLE CALCULATION

### 7.1 ERP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol.	ERP	
channel	Freq.(MHz)						W	dBm
128	824.20	-21.37	38.40	-10.61	0.95	H	0.483	26.84

$$\text{ERP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test , the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of effective radiated power.

### 7.2 EIRP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol.	EIRP	
channel	Freq.(MHz)						W	dBm
20175	1,732.50	-15.75	18.45	9.90	1.76	H	0.456	26.59

$$\text{EIRP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test , the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of equivalent isotropic radiated power.

7.3. Emission Designator

GSM Emission Designator

Emission Designator = 249KGXW

GSM BW = 249 kHz

G = Phase Modulation

X = Cases not otherwise covered

W = Combination (Audio/Data)

EDGE Emission Designator

Emission Designator = 249KG7W

GSM BW = 249 kHz

G = Phase Modulation

7 = Quantized/Digital Info

W = Combination (Audio/Data)

WCDMA Emission Designator

Emission Designator = 4M17F9W

WCDMA BW = 4.17 MHz

F = Frequency Modulation

9 = Composite Digital Info

W = Combination (Audio/Data)

QPSK Modulation

Emission Designator = 4M48G7D

LTE BW = 4.48 MHz

G = Phase Modulation

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

QAM Modulation

Emission Designator = 4M48W7D

LTE BW = 4.48 MHz

W = Amplitude/Angle Modulated

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

## 8. TEST DATA

### 8.1 EFFECTIVE RADIATED POWER

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol	Limit W	ERP	
									W	dBm
699.7	LTE B12 (1.4 MHz)	QPSK	-30.78	28.97	-9.89	1.29	V	< 3.00	0.060	17.79
		16-QAM	-31.64	28.11	-9.89	1.29	V		0.049	16.93
		64-QAM	-32.64	27.11	-9.89	1.29	V		0.039	15.93
		256-QAM	-35.56	24.19	-9.89	1.29	V		0.020	13.01
707.5		QPSK	-32.11	27.88	-9.80	1.29	V		0.048	16.79
		16-QAM	-33.04	26.95	-9.80	1.29	V		0.039	15.86
		64-QAM	-33.97	26.02	-9.80	1.29	V		0.031	14.93
		256-QAM	-36.92	23.07	-9.80	1.29	V		0.016	11.98
715.3		QPSK	-30.87	28.97	-9.78	1.30	V		0.062	17.89
		16-QAM	-31.71	28.13	-9.78	1.30	V		0.051	17.05
		64-QAM	-32.73	27.11	-9.78	1.30	V		0.040	16.03
		256-QAM	-35.70	24.14	-9.78	1.30	V		0.020	13.06

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol	Limit W	ERP	
									W	dBm
700.5	LTE B12 (3 MHz)	QPSK	-30.79	9.28	9.86	1.29	V	< 3.00	0.061	17.84
		16-QAM	-31.67	8.40	9.86	1.29	V		0.050	16.96
		64-QAM	-32.65	7.42	9.86	1.29	V		0.040	15.98
		256-QAM	-35.54	4.53	9.86	1.29	V		0.020	13.09
707.5		QPSK	-32.03	27.96	-9.80	1.29	V		0.049	16.87
		16-QAM	-32.85	27.14	-9.80	1.29	V		0.040	16.05
		64-QAM	-33.85	26.14	-9.80	1.29	V		0.032	15.05
		256-QAM	-36.79	23.20	-9.80	1.29	V		0.016	12.11
714.5		QPSK	-30.85	28.97	-9.79	1.30	V		0.061	17.88
		16-QAM	-31.64	28.18	-9.79	1.30	V		0.051	17.09
		64-QAM	-32.67	27.15	-9.79	1.30	V		0.040	16.06
		256-QAM	-35.66	24.16	-9.79	1.30	V		0.020	13.07

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol	Limit W	ERP	
									W	dBm
701.5	LTE B12 (5 MHz)	QPSK	-30.80	28.97	-9.82	1.29	V	< 3.00	0.061	17.86
		16-QAM	-31.65	28.12	-9.82	1.29	V		0.050	17.01
		64-QAM	-32.64	27.13	-9.82	1.29	V		0.040	16.02
		256-QAM	-35.52	24.25	-9.82	1.29	V		0.021	13.14
707.5		QPSK	-31.88	28.11	-9.80	1.29	V		0.050	17.02
		16-QAM	-32.81	27.18	-9.80	1.29	V		0.041	16.09
		64-QAM	-33.75	26.24	-9.80	1.29	V		0.033	15.15
		256-QAM	-36.71	23.28	-9.80	1.29	V		0.017	12.19
713.5		QPSK	-30.83	28.97	-9.79	1.30	V		0.061	17.88
		16-QAM	-31.74	28.06	-9.79	1.30	V		0.050	16.97
		64-QAM	-32.65	27.15	-9.79	1.30	V		0.040	16.06
		256-QAM	-35.70	24.10	-9.79	1.30	V		0.020	13.01

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol	Limit W	ERP	
									W	dBm
704.0	LTE B12 (10 MHz)	QPSK	-30.78	29.08	-9.81	1.29	V	< 3.00	0.063	17.98
		16-QAM	-31.68	28.18	-9.81	1.29	V		0.051	17.08
		64-QAM	-32.68	27.18	-9.81	1.29	V		0.041	16.08
		256-QAM	-35.53	24.33	-9.81	1.29	V		0.021	13.23
707.5		QPSK	-31.57	28.42	-9.80	1.29	V		0.054	17.33
		16-QAM	-32.33	27.66	-9.80	1.29	V		0.045	16.57
		64-QAM	-33.43	26.56	-9.80	1.29	V		0.035	15.47
		256-QAM	-36.35	23.64	-9.80	1.29	V		0.018	12.55
711.0		QPSK	-30.99	28.77	-9.79	1.29	V		0.059	17.69
		16-QAM	-31.82	27.94	-9.79	1.29	V		0.049	16.86
		64-QAM	-32.84	26.92	-9.79	1.29	V		0.038	15.84
		256-QAM	-35.77	23.99	-9.79	1.29	V		0.020	12.91

**8.2 RADIATED SPURIOUS EMISSIONS**

- ▣ MODE: LTE B12
- ▣ MODULATION SIGNAL: 10 MHz QPSK
- ▣ DISTANCE: 3 meters

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	Limit
23060 (704.0)	1 408.00	-51.78	7.68	-61.20	1.84	V	-55.36	-13.00
	2 112.00	-54.04	9.52	-58.53	2.33	V	-51.34	-13.00
	2 816.00	-57.18	10.80	-58.52	2.69	V	-50.40	-13.00
23095 (707.5)	1 415.00	-52.44	7.72	-61.56	1.85	H	-55.69	-13.00
	2 122.50	-56.24	9.44	-59.46	2.31	H	-52.33	-13.00
	2 830.00	-57.53	10.80	-59.11	2.69	H	-51.00	-13.00
23130 (711.0)	1 422.00	-51.32	7.76	-60.13	1.86	V	-54.23	-13.00
	2 133.00	-56.27	9.36	-60.06	2.30	H	-53.00	-13.00
	2 844.00	-57.66	10.80	-59.56	2.71	H	-51.47	-13.00

**8.3 OCCUPIED BANDWIDTH**

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
12	1.4 MHz	707.5	QPSK	6	0	1.0964
			16-QAM			1.0990
			64-QAM			1.0946
			256-QAM			1.0969
	3 MHz		QPSK	15		2.7122
			16-QAM			2.7033
			64-QAM			2.7106
			256-QAM			2.7047
	5 MHz		QPSK	25		4.5119
			16-QAM			4.5109
			64-QAM			4.5089
			256-QAM			4.5240
	10 MHz		QPSK	50		8.9947
			16-QAM			9.0051
			64-QAM			9.0284
			256-QAM			8.9802

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 39 ~ 54.



**8.4 CONDUCTED SPURIOUS EMISSIONS**

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
12	1.4	699.7	3.7044	27.976	-67.216	-39.240	-13.00
		707.5	3.7189	27.976	-67.052	-39.076	
		715.3	3.7204	27.976	-67.415	-39.439	
	3	700.5	3.7079	27.976	-67.262	-39.286	
		707.5	3.7000	27.976	-67.089	-39.113	
		714.5	3.7104	27.976	-67.260	-39.284	
	5	701.5	3.7119	27.976	-67.014	-39.038	
		707.5	3.6945	27.976	-67.102	-39.126	
		713.5	3.6860	27.976	-67.335	-39.359	
	10	704.0	3.6890	27.976	-67.368	-39.392	
		707.5	3.6920	27.976	-67.027	-39.051	
		711.0	3.6855	27.976	-67.035	-39.059	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 83 ~ 94.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor (dB) = Cable Loss + Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

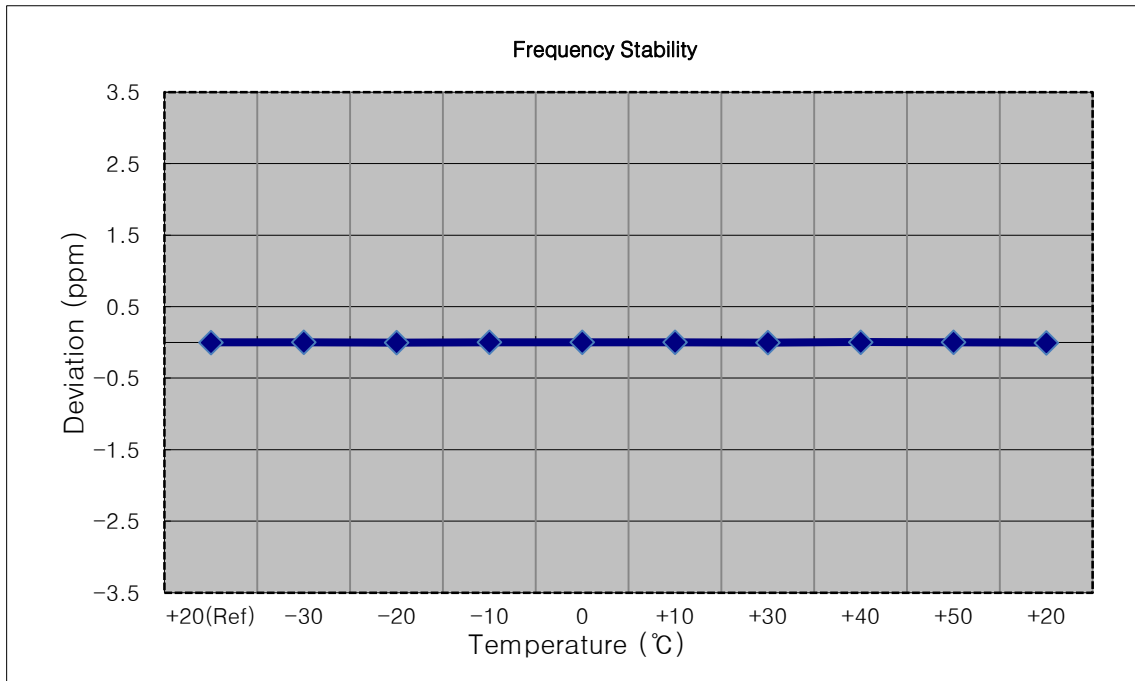
**8.5 BAND EDGE**

- Plots of the EUT's Band Edge are shown Page 55 ~ 82.

**8.6 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE**

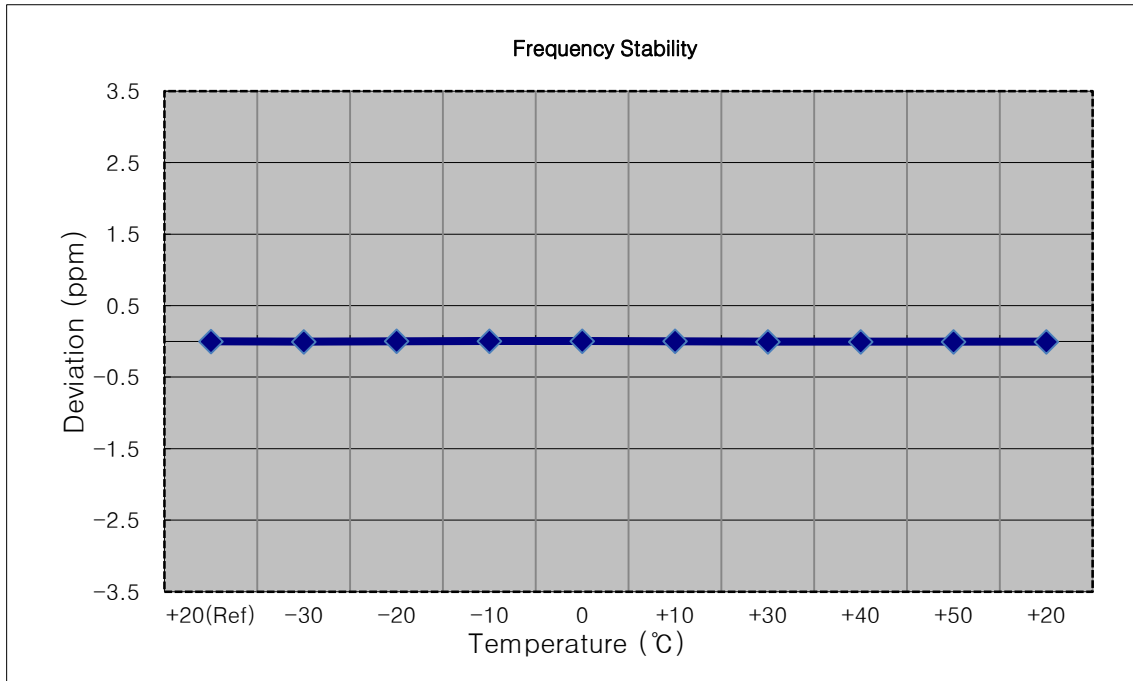
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 699,700,000 Hz
- ▣ CHANNEL: 23017 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	699 699 998	0.0	0.000 000	0.000
100 %		-30	699 699 999	1.8	0.000 000	0.003
100 %		-20	699 699 996	-1.5	0.000 000	-0.002
100 %		-10	699 699 999	1.0	0.000 000	0.001
100 %		0	699 699 999	1.7	0.000 000	0.002
100 %		+10	699 700 000	2.2	0.000 000	0.003
100 %		+30	699 699 996	-1.9	0.000 000	-0.003
100 %		+40	699 700 000	2.4	0.000 000	0.003
100 %		+50	699 700 000	2.3	0.000 000	0.003
Batt. Endpoint		3.550	+20	699 699 994	-3.7	-0.000 001



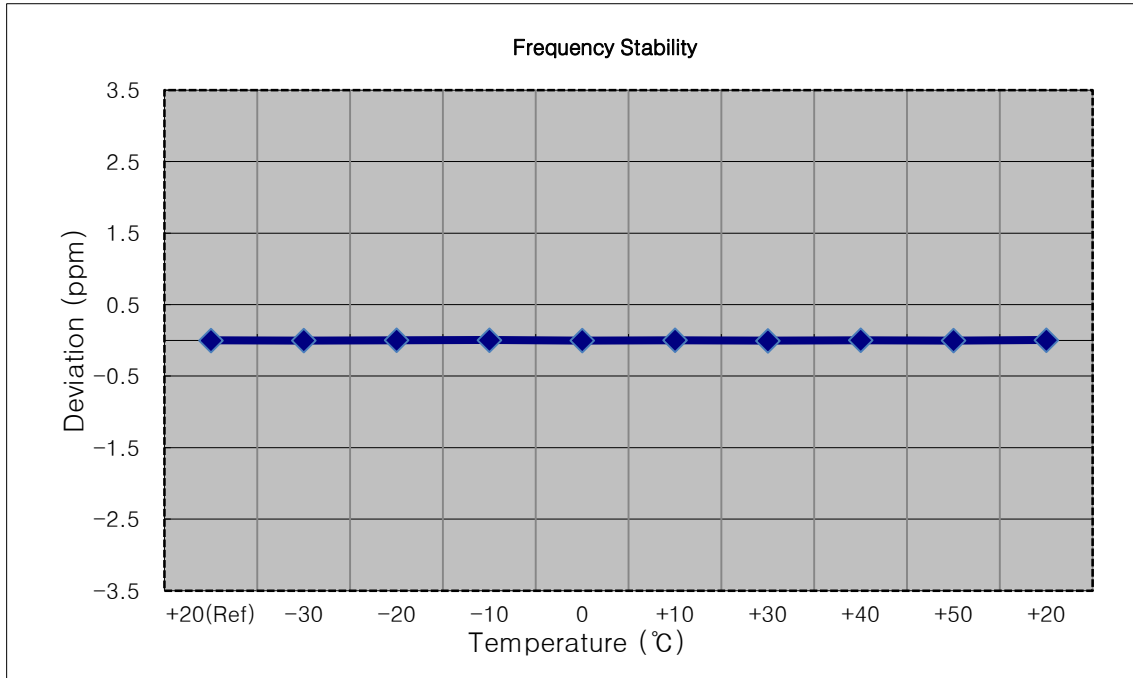
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 700,500,000 Hz
- ▣ CHANNEL: 23025 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	700 499 998	0.0	0.000 000	0.000
100 %		-30	700 499 996	-2.8	0.000 000	-0.004
100 %		-20	700 500 000	1.6	0.000 000	0.002
100 %		-10	700 500 002	3.7	0.000 001	0.005
100 %		0	700 500 001	2.9	0.000 000	0.004
100 %		+10	700 500 000	1.5	0.000 000	0.002
100 %		+30	700 499 995	-3.4	0.000 000	-0.005
100 %		+40	700 499 995	-3.4	0.000 000	-0.005
100 %		+50	700 499 996	-2.4	0.000 000	-0.003
Batt. Endpoint		3.550	+20	700 499 996	-2.5	0.000 000



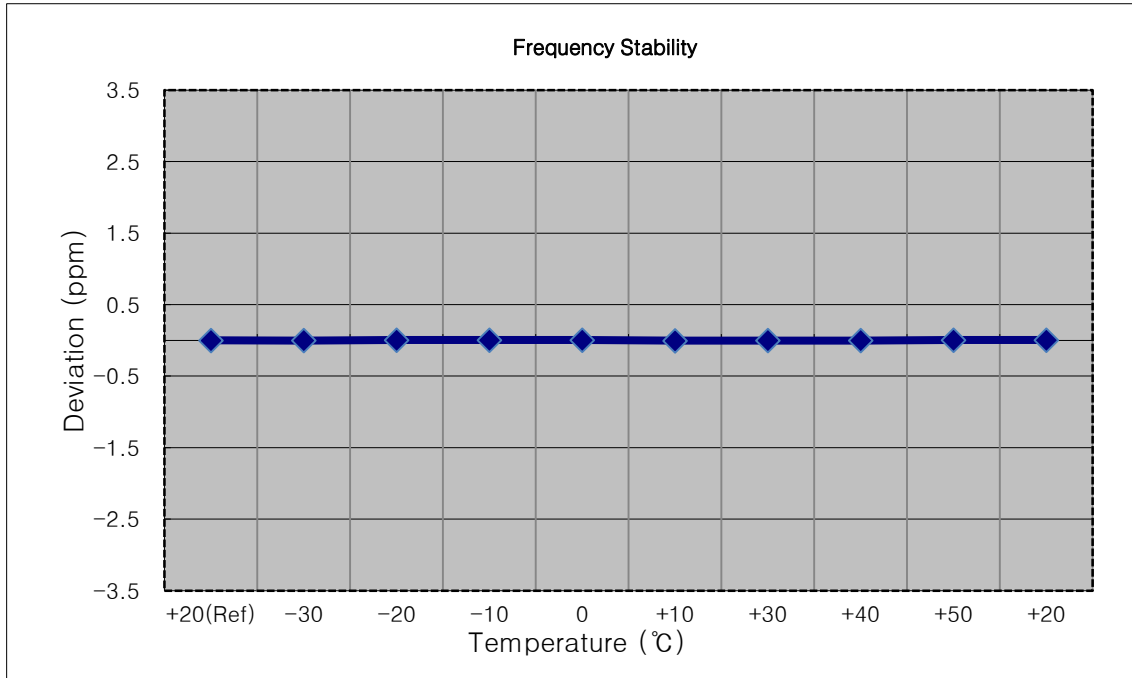
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 701,500,000 Hz
- ▣ CHANNEL: 23035 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	701 499 996	0.0	0.000 000	0.000
100 %		-30	701 499 994	-2.3	0.000 000	-0.003
100 %		-20	701 499 998	1.9	0.000 000	0.003
100 %		-10	701 499 999	3.0	0.000 000	0.004
100 %		0	701 499 994	-2.2	0.000 000	-0.003
100 %		+10	701 499 999	2.2	0.000 000	0.003
100 %		+30	701 499 993	-3.0	0.000 000	-0.004
100 %		+40	701 499 998	1.9	0.000 000	0.003
100 %		+50	701 499 995	-1.8	0.000 000	-0.003
Batt. Endpoint	3.550	+20	701 499 999	2.4	0.000 000	0.003



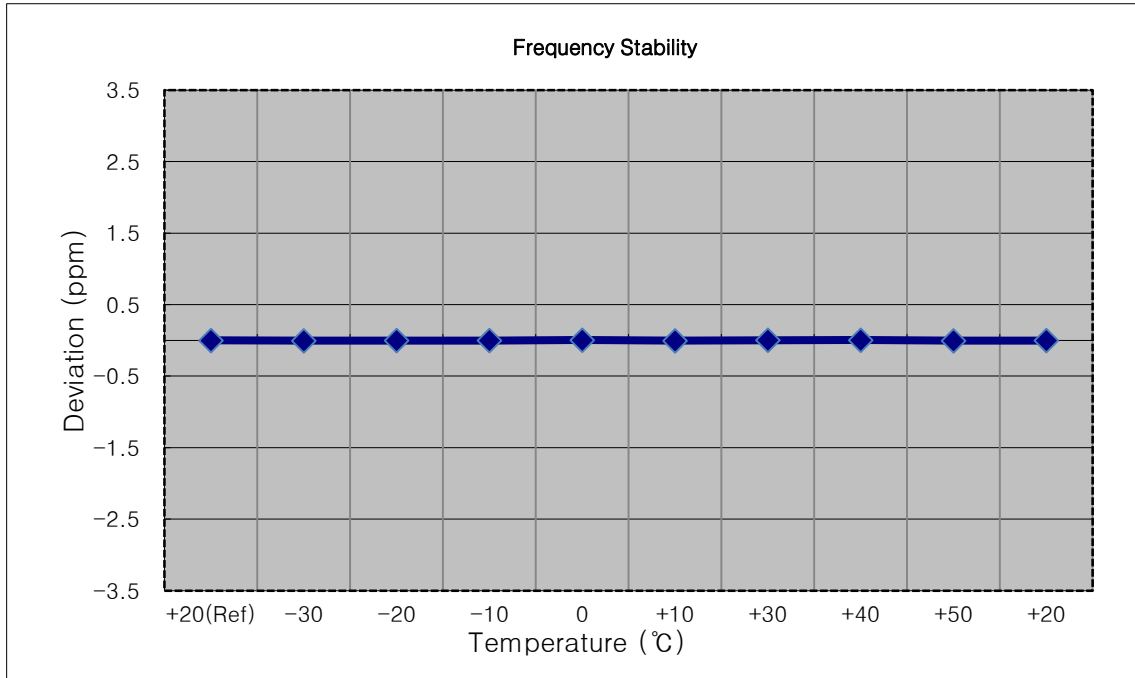
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 704,000,000 Hz
- ▣ CHANNEL: 23060 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	704 000 003	0.0	0.000 000	0.000
100 %		-30	704 000 001	-1.9	0.000 000	-0.003
100 %		-20	704 000 005	2.9	0.000 000	0.004
100 %		-10	704 000 005	2.9	0.000 000	0.004
100 %		0	704 000 005	2.4	0.000 000	0.003
100 %		+10	704 000 000	-2.9	0.000 000	-0.004
100 %		+30	704 000 000	-2.3	0.000 000	-0.003
100 %		+40	704 000 001	-2.0	0.000 000	-0.003
100 %		+50	704 000 006	3.4	0.000 000	0.005
Batt. Endpoint	3.550	+20	704 000 006	3.4	0.000 000	0.005



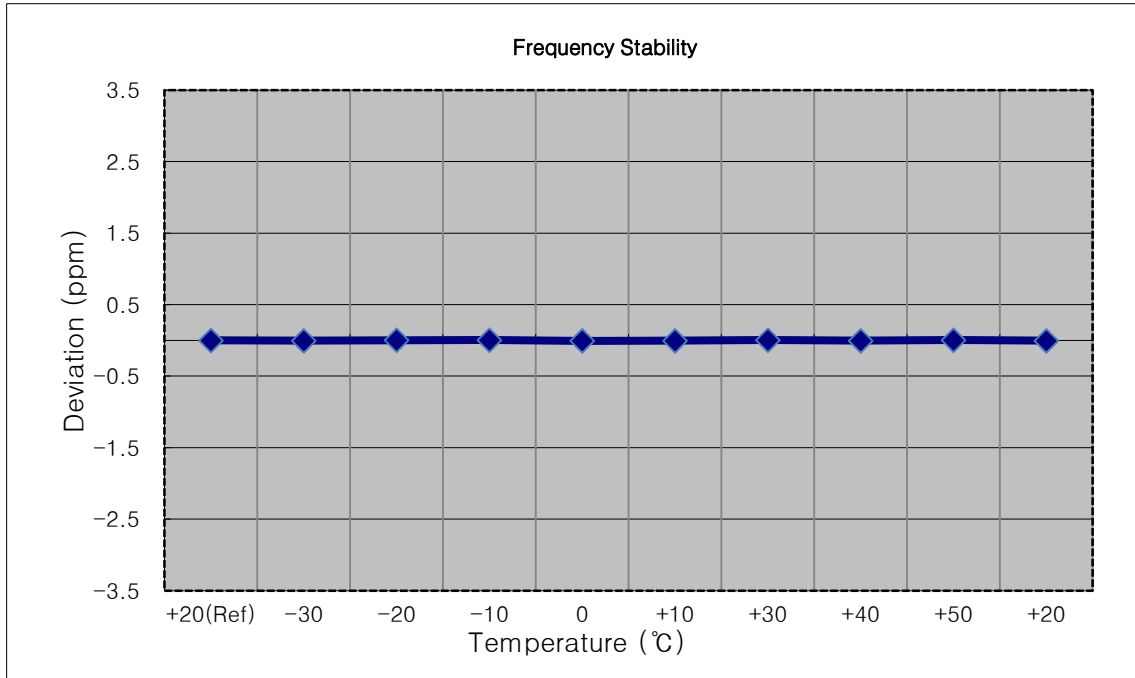
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	707 499 998	0.0	0.000 000	0.000
100 %		-30	707 499 994	-3.2	0.000 000	-0.005
100 %		-20	707 499 995	-2.3	0.000 000	-0.003
100 %		-10	707 499 996	-2.1	0.000 000	-0.003
100 %		0	707 500 001	2.9	0.000 000	0.004
100 %		+10	707 499 995	-2.8	0.000 000	-0.004
100 %		+30	707 500 000	2.3	0.000 000	0.003
100 %		+40	707 500 000	2.4	0.000 000	0.003
100 %		+50	707 499 995	-2.8	0.000 000	-0.004
Batt. Endpoint	3.550	+20	707 499 996	-2.0	0.000 000	-0.003



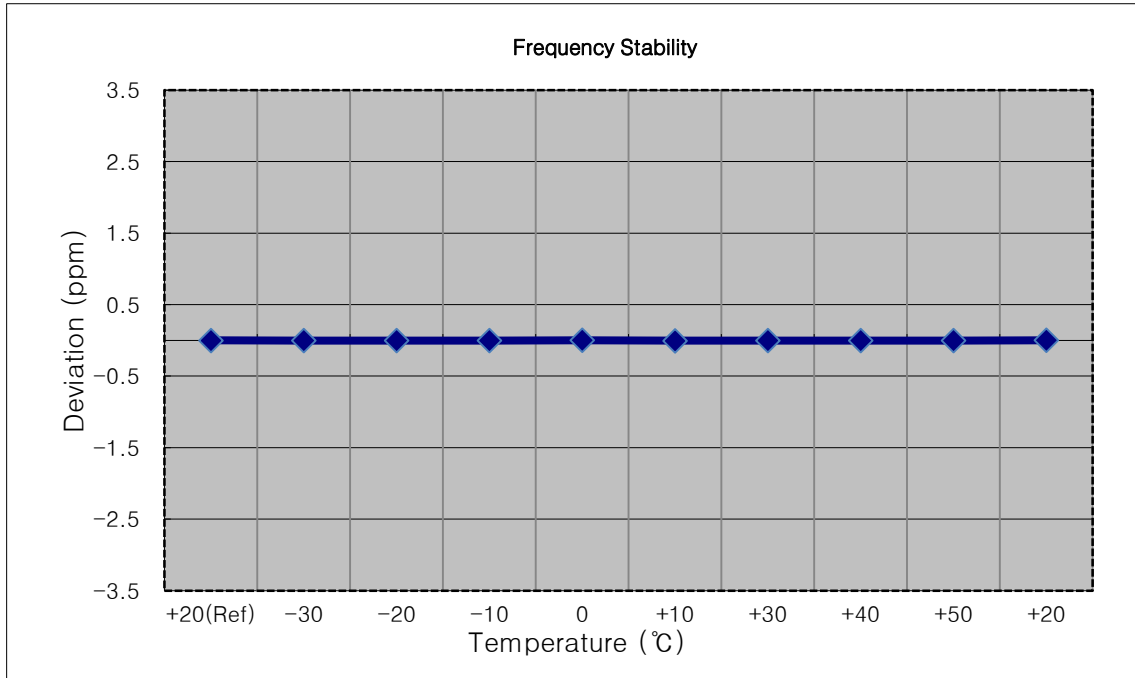
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	707 499 999	0.0	0.000 000	0.000
100 %		-30	707 499 995	-3.5	0.000 000	-0.005
100 %		-20	707 500 000	1.6	0.000 000	0.002
100 %		-10	707 500 001	2.5	0.000 000	0.004
100 %		0	707 499 994	-4.6	-0.000 001	-0.007
100 %		+10	707 499 996	-2.7	0.000 000	-0.004
100 %		+30	707 500 001	2.7	0.000 000	0.004
100 %		+40	707 499 996	-2.5	0.000 000	-0.004
100 %		+50	707 500 002	3.3	0.000 000	0.005
Batt. Endpoint	3.550	+20	707 499 996	-2.9	0.000 000	-0.004



- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

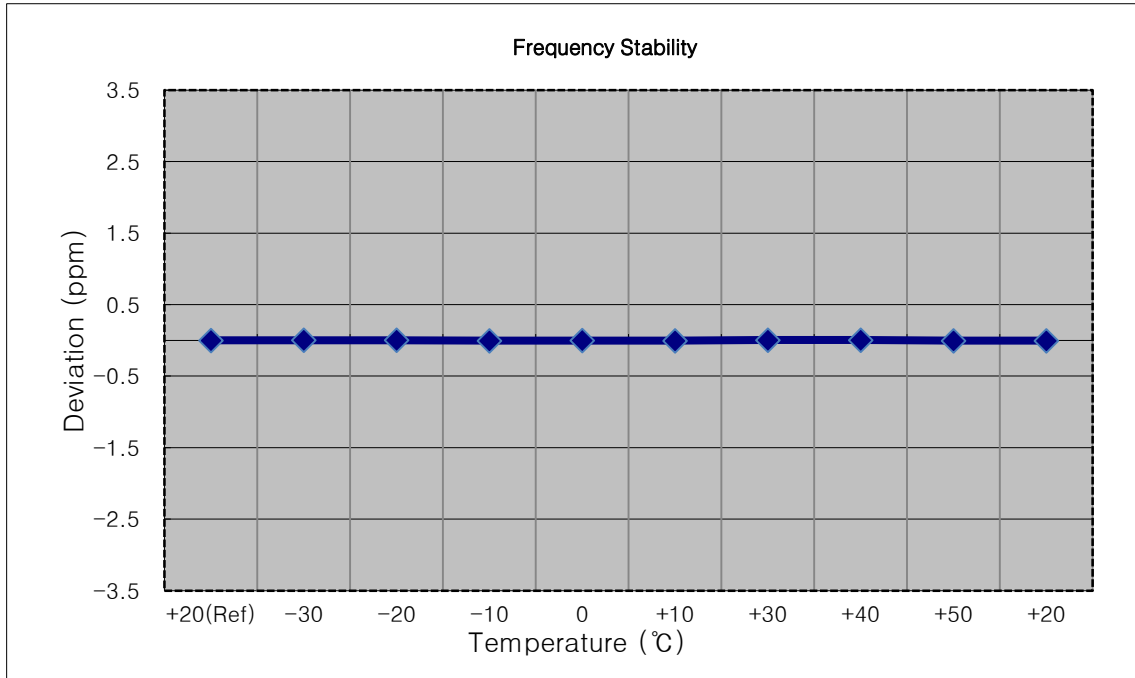
Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	707 500 003	0.0	0.000 000	0.000
100 %		-30	707 500 001	-2.0	0.000 000	-0.003
100 %		-20	707 500 001	-1.7	0.000 000	-0.002
100 %		-10	707 500 001	-2.2	0.000 000	-0.003
100 %		0	707 500 005	2.0	0.000 000	0.003
100 %		+10	707 500 000	-2.6	0.000 000	-0.004
100 %		+30	707 500 001	-1.8	0.000 000	-0.003
100 %		+40	707 500 001	-1.9	0.000 000	-0.003
100 %		+50	707 500 001	-2.0	0.000 000	-0.003
Batt. Endpoint	3.550	+20	707 500 005	2.2	0.000 000	0.003





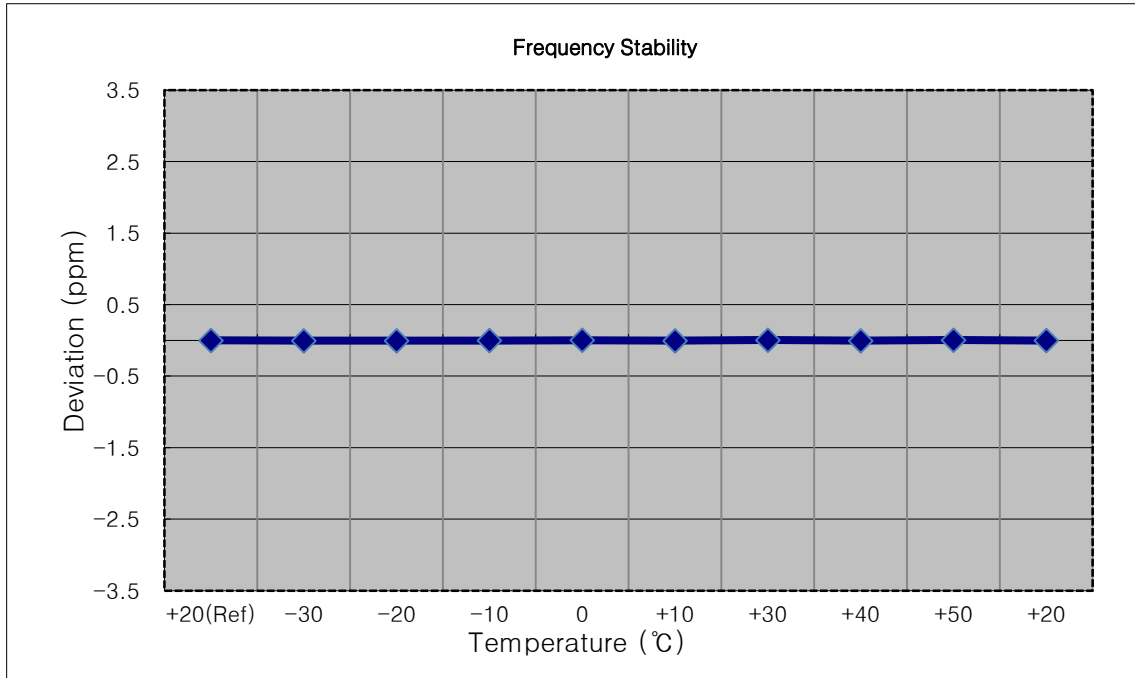
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	707 500 001	0.0	0.000 000	0.000
100 %		-30	707 500 004	2.3	0.000 000	0.003
100 %		-20	707 500 003	2.0	0.000 000	0.003
100 %		-10	707 499 999	-2.8	0.000 000	-0.004
100 %		0	707 500 000	-1.9	0.000 000	-0.003
100 %		+10	707 499 998	-3.5	0.000 000	-0.005
100 %		+30	707 500 004	2.4	0.000 000	0.003
100 %		+40	707 500 004	2.5	0.000 000	0.004
100 %		+50	707 499 999	-2.6	0.000 000	-0.004
Batt. Endpoint	3.550	+20	707 499 999	-2.7	0.000 000	-0.004



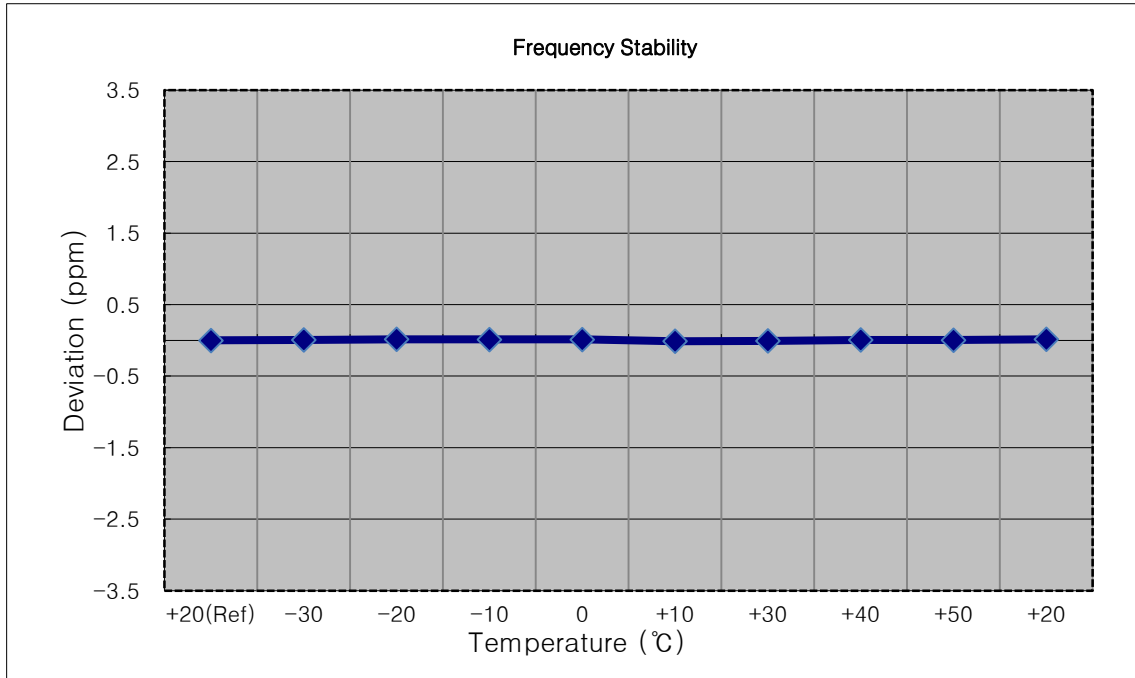
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 715,300,000 Hz
- ▣ CHANNEL: 23173 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	715 300 003	0.0	0.000 000	0.000
100 %		-30	715 300 000	-3.8	-0.000 001	-0.005
100 %		-20	715 300 000	-3.0	0.000 000	-0.004
100 %		-10	715 300 001	-2.3	0.000 000	-0.003
100 %		0	715 300 005	1.6	0.000 000	0.002
100 %		+10	715 300 000	-3.7	-0.000 001	-0.005
100 %		+30	715 300 007	3.2	0.000 000	0.004
100 %		+40	715 300 000	-3.0	0.000 000	-0.004
100 %		+50	715 300 006	2.6	0.000 000	0.004
Batt. Endpoint	3.550	+20	715 300 001	-2.1	0.000 000	-0.003



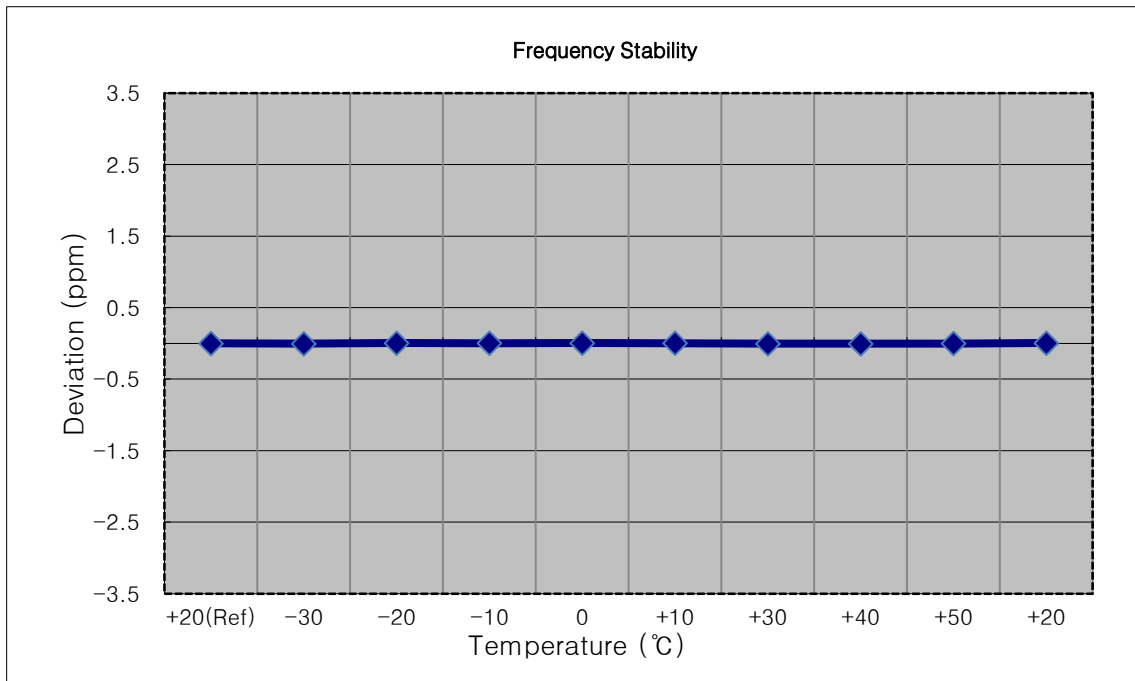
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 714,500,000 Hz
- ▣ CHANNEL: 23165 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	714 499 994	0.0	0.000 000	0.000
100 %		-30	714 499 999	4.7	0.000 001	0.007
100 %		-20	714 500 005	10.8	0.000 002	0.015
100 %		-10	714 500 004	10.1	0.000 001	0.014
100 %		0	714 500 004	10.3	0.000 001	0.014
100 %		+10	714 499 987	-7.5	-0.000 001	-0.010
100 %		+30	714 499 989	-4.6	-0.000 001	-0.006
100 %		+40	714 499 999	4.8	0.000 001	0.007
100 %		+50	714 499 997	2.8	0.000 000	0.004
Batt. Endpoint		3.550	+20	714 500 005	10.9	0.000 002



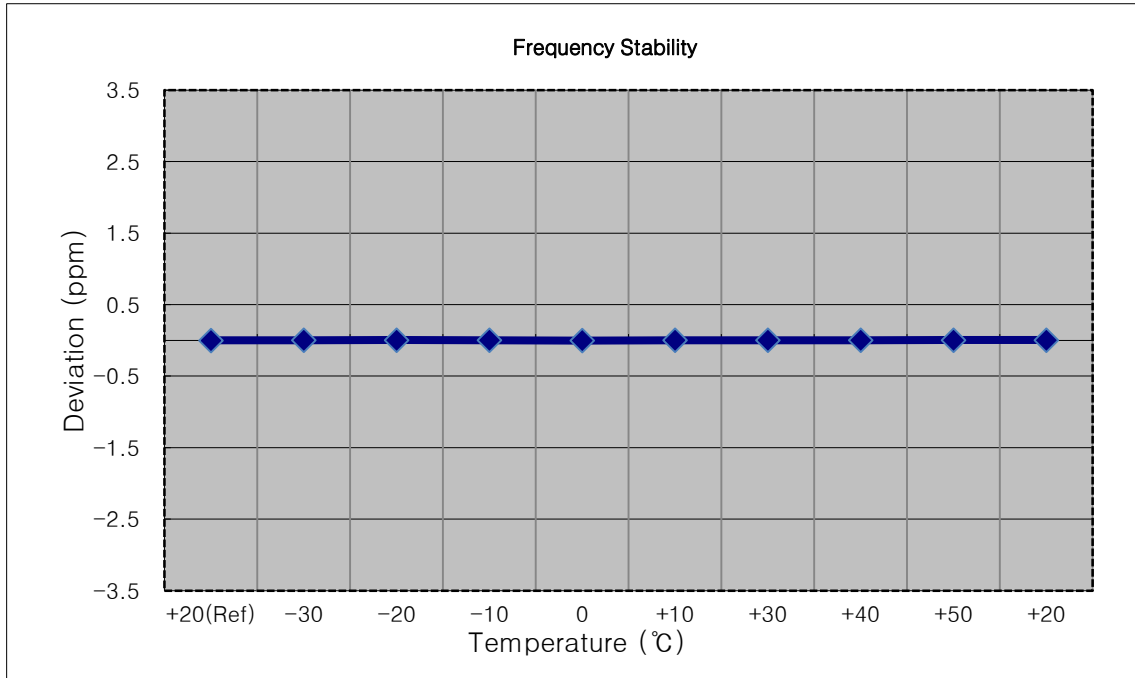
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 713,500,000 Hz
- ▣ CHANNEL: 23155 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	713 500 001	0.0	0.000 000	0.000
100 %		-30	713 499 998	-3.8	-0.000 001	-0.005
100 %		-20	713 500 005	3.6	0.000 001	0.005
100 %		-10	713 500 003	2.0	0.000 000	0.003
100 %		0	713 500 005	3.3	0.000 000	0.005
100 %		+10	713 500 003	1.5	0.000 000	0.002
100 %		+30	713 499 999	-2.5	0.000 000	-0.004
100 %		+40	713 499 998	-3.1	0.000 000	-0.004
100 %		+50	713 500 000	-1.8	0.000 000	-0.003
Batt. Endpoint	3.550	+20	713 500 004	2.9	0.000 000	0.004



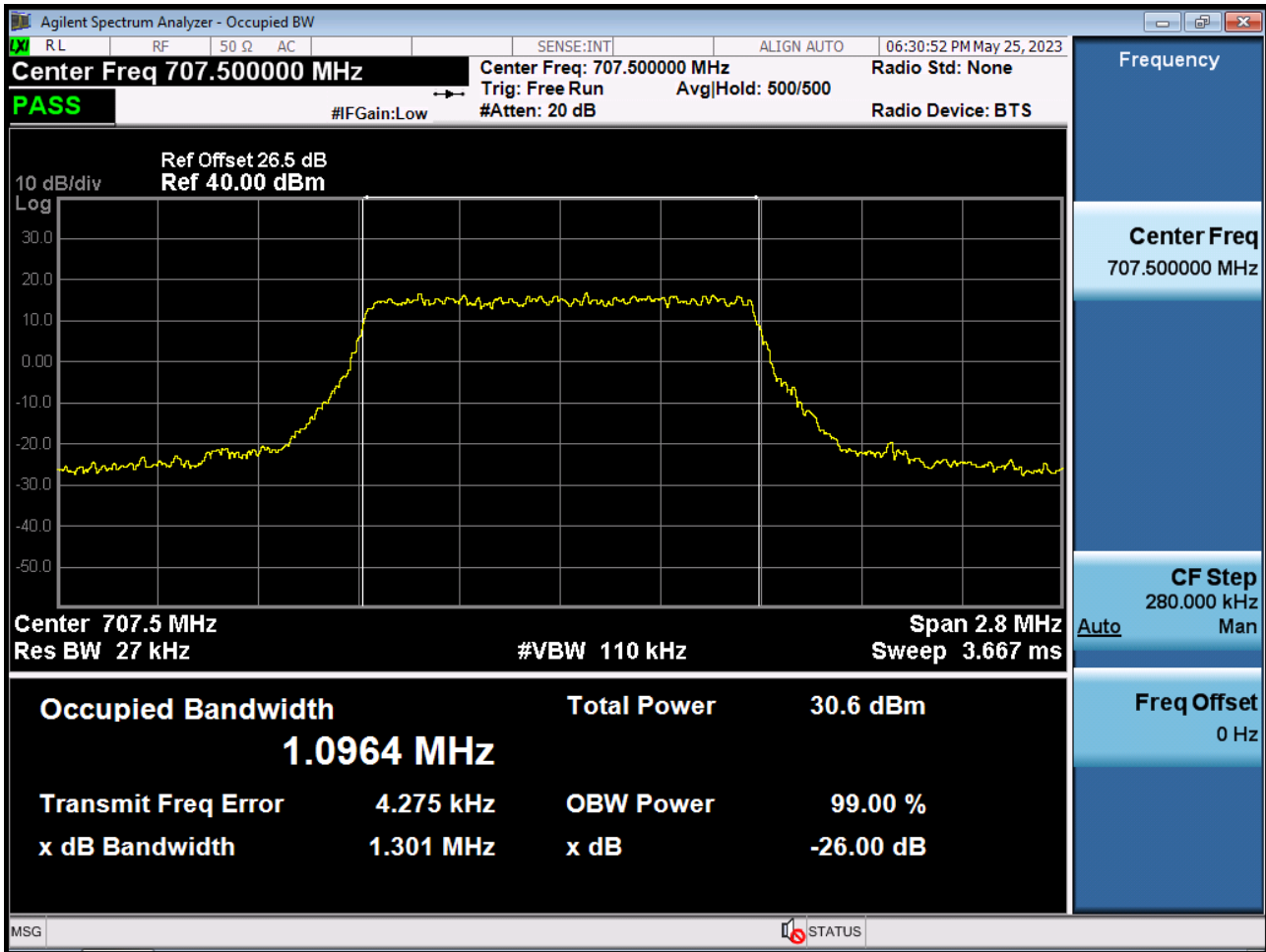
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 711,000,000 Hz
- ▣ CHANNEL: 23130 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	710 999 998	0.0	0.000 000	0.000
100 %		-30	711 000 000	2.1	0.000 000	0.003
100 %		-20	711 000 001	3.0	0.000 000	0.004
100 %		-10	711 000 000	2.0	0.000 000	0.003
100 %		0	710 999 996	-2.4	0.000 000	-0.003
100 %		+10	711 000 000	1.8	0.000 000	0.003
100 %		+30	710 999 999	1.2	0.000 000	0.002
100 %		+40	711 000 000	2.2	0.000 000	0.003
100 %		+50	711 000 001	3.0	0.000 000	0.004
Batt. Endpoint	3.550	+20	711 000 000	2.4	0.000 000	0.003

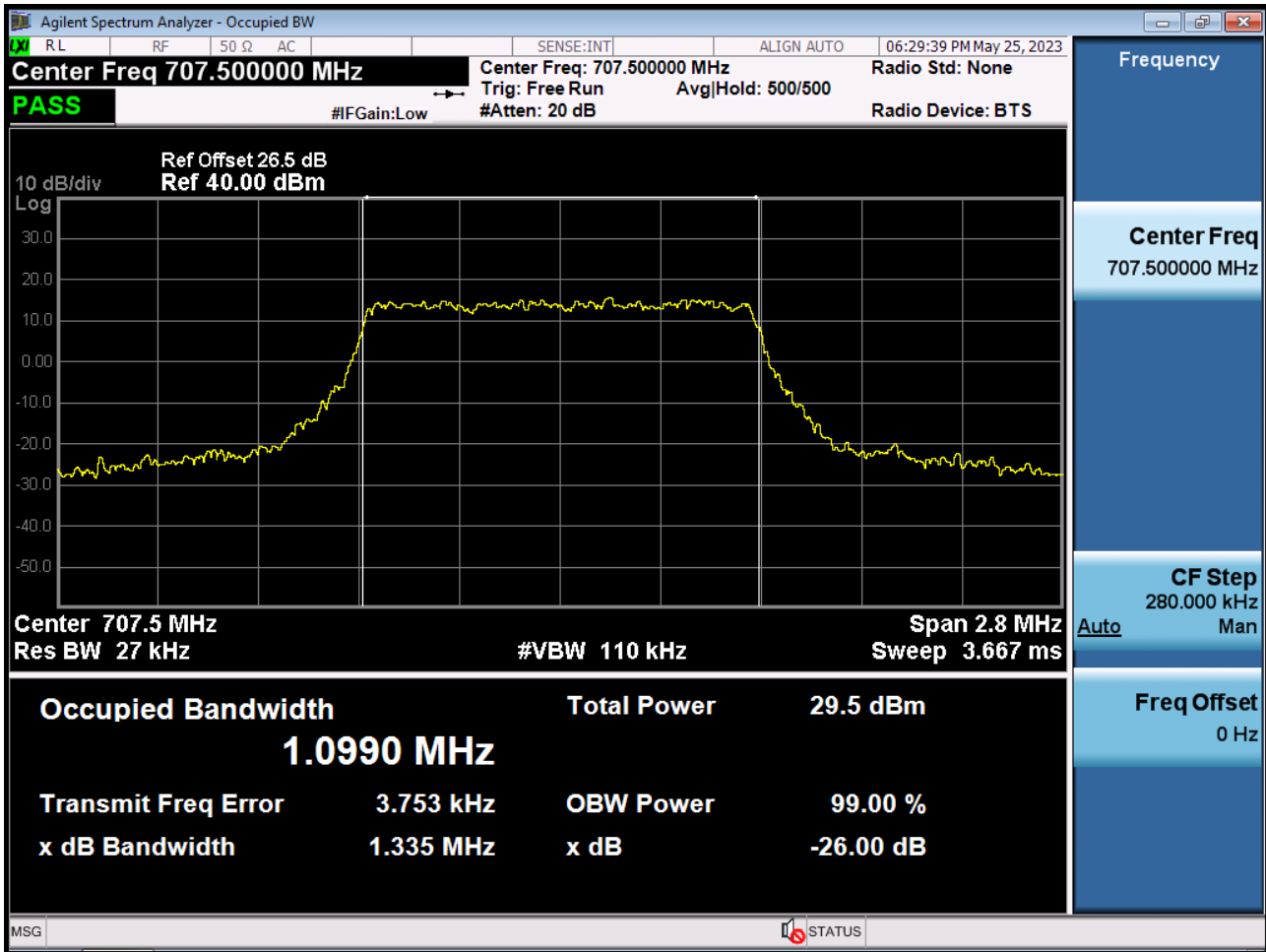


## 9. TEST PLOTS

BAND 12. Occupied Bandwidth Plot (1.4 M BW Ch.23095 QPSK\_RB6\_0)

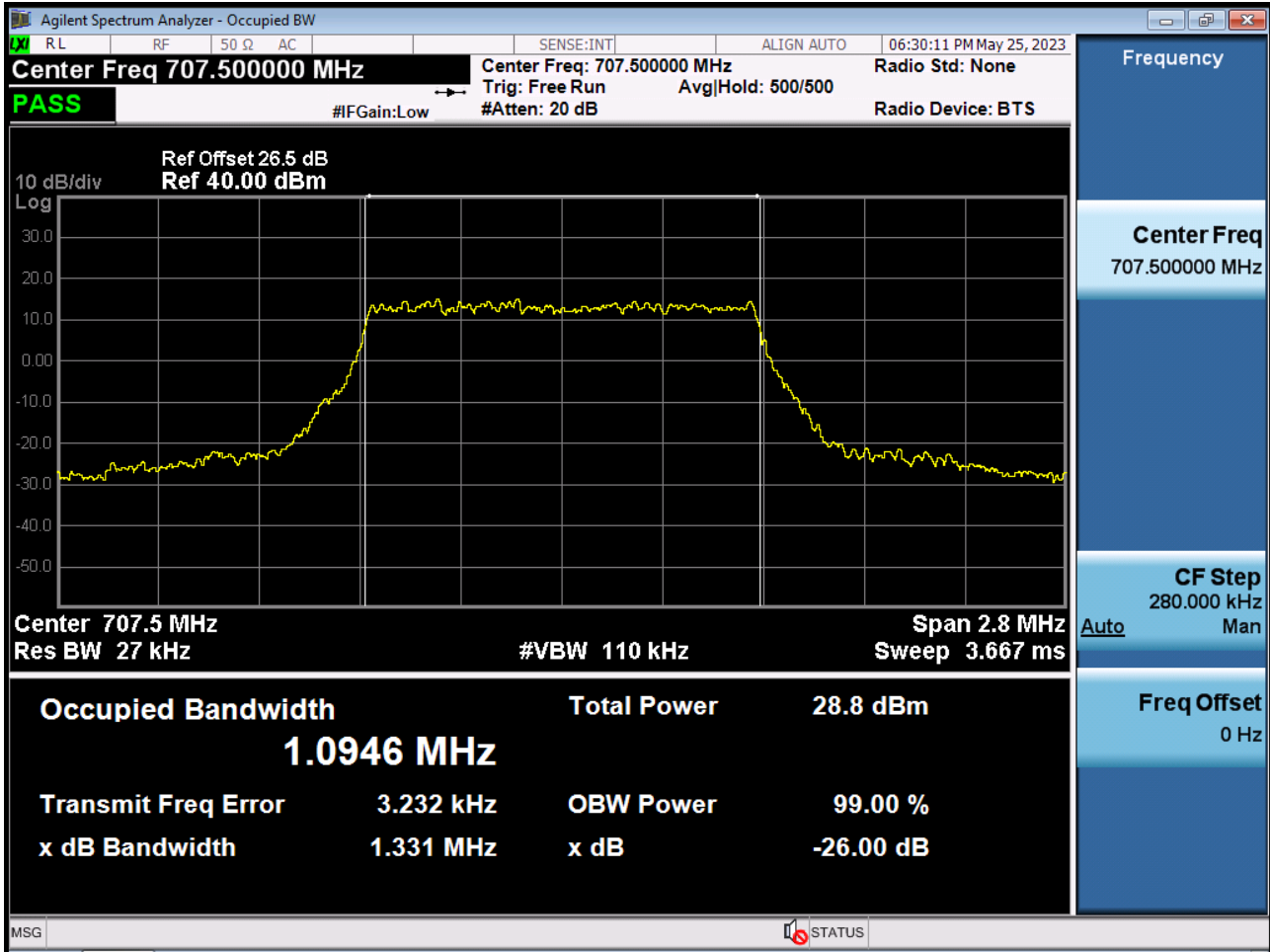


BAND 12. Occupied Bandwidth Plot (1.4 M BW Ch.23095 16QAM\_RB6\_0)

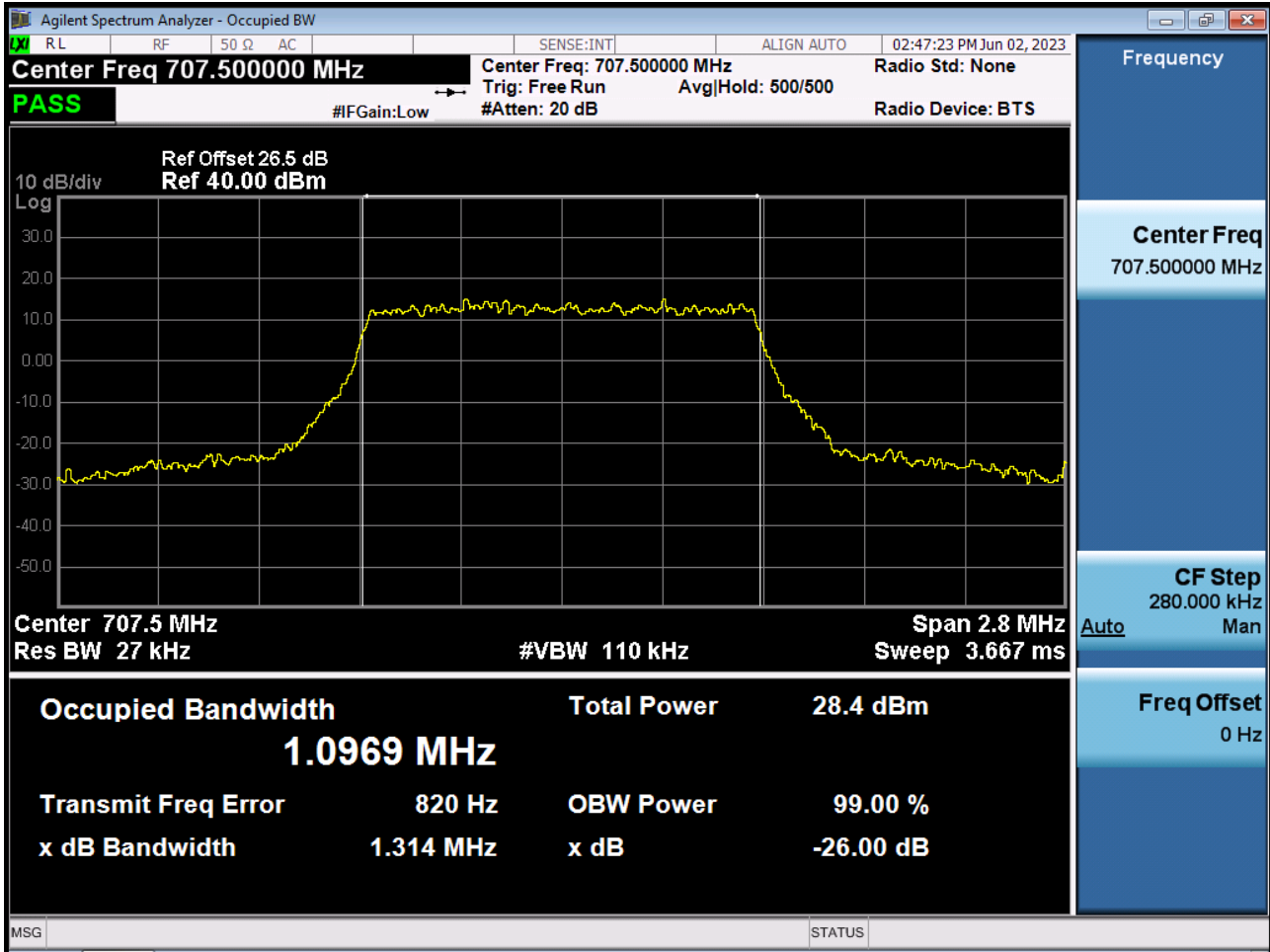




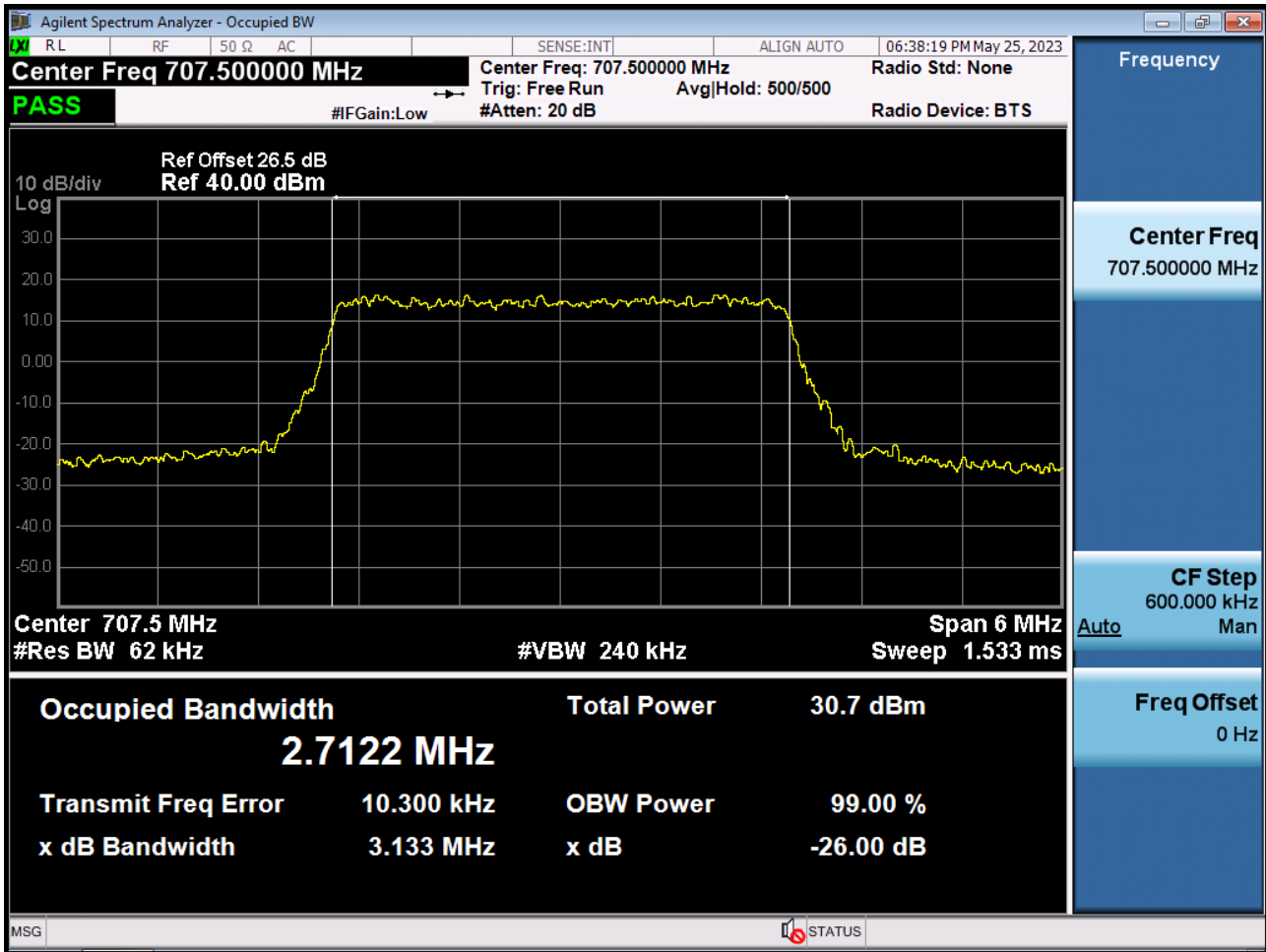
BAND 12. Occupied Bandwidth Plot (1.4 M BW Ch.23095 64QAM\_RB6\_0)



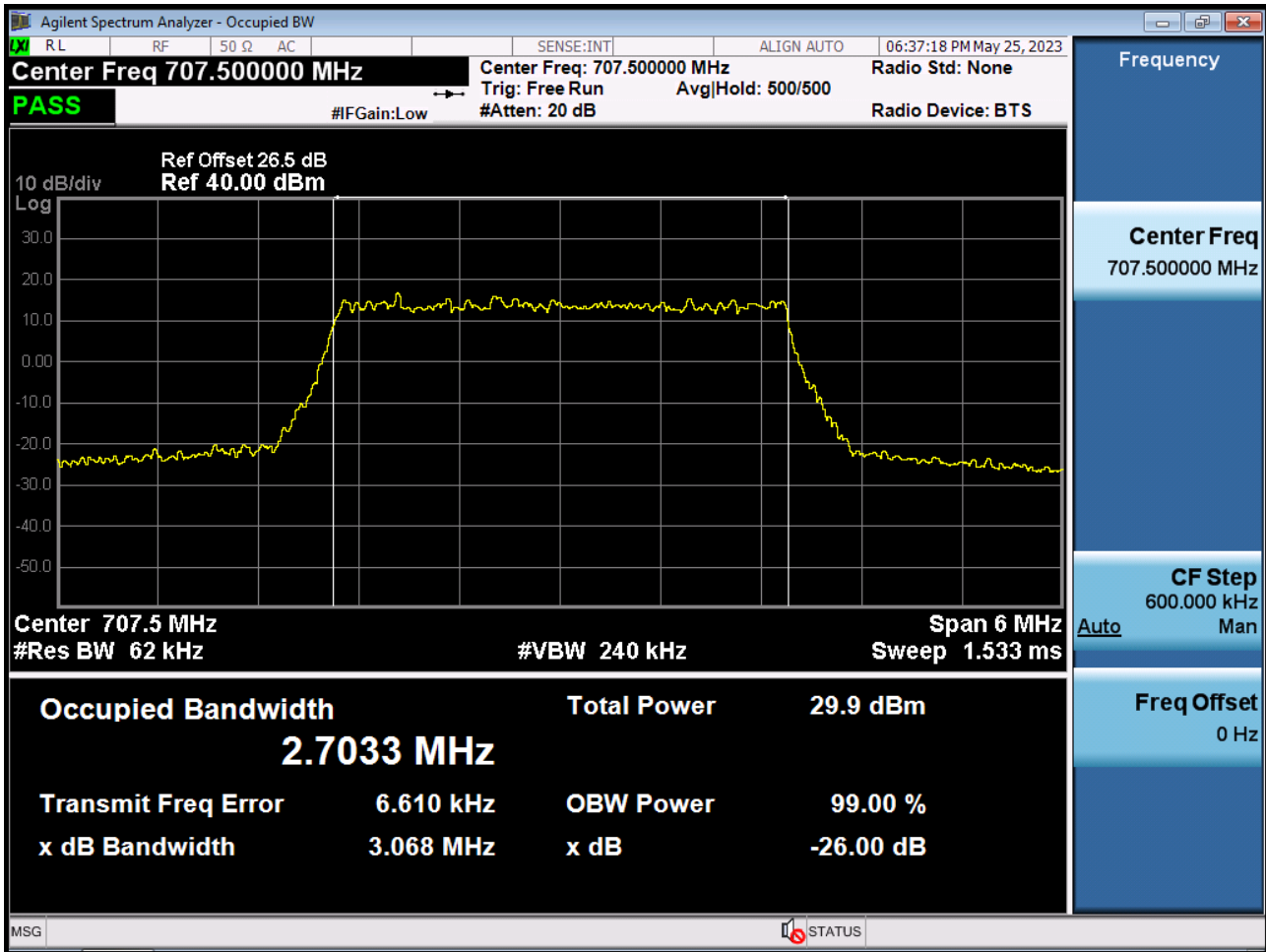
BAND 12. Occupied Bandwidth Plot (1.4 M BW Ch.23095 256QAM\_RB6\_0)



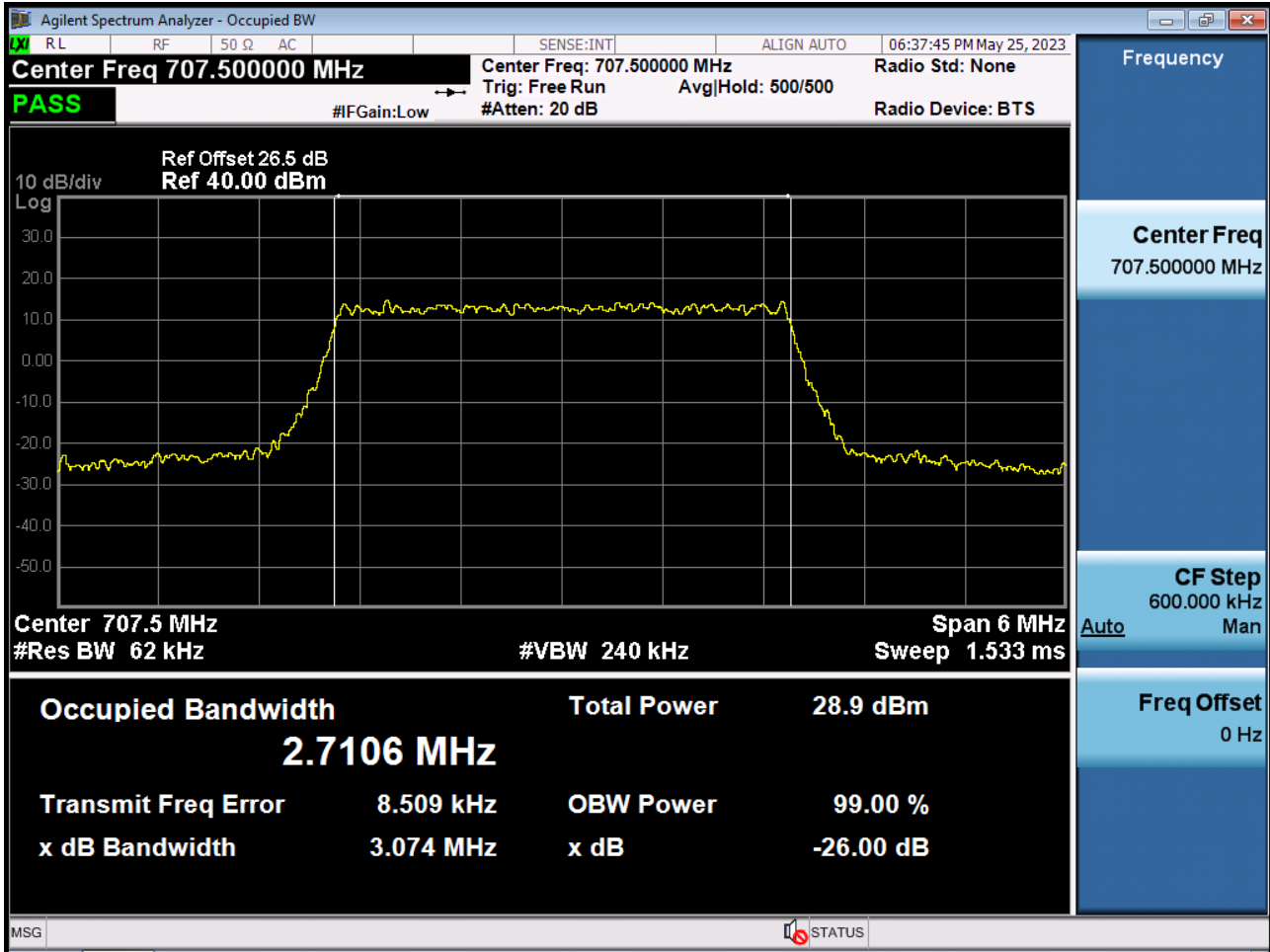
BAND 12. Occupied Bandwidth Plot (3 M BW Ch.23095 QPSK\_RB15\_0)



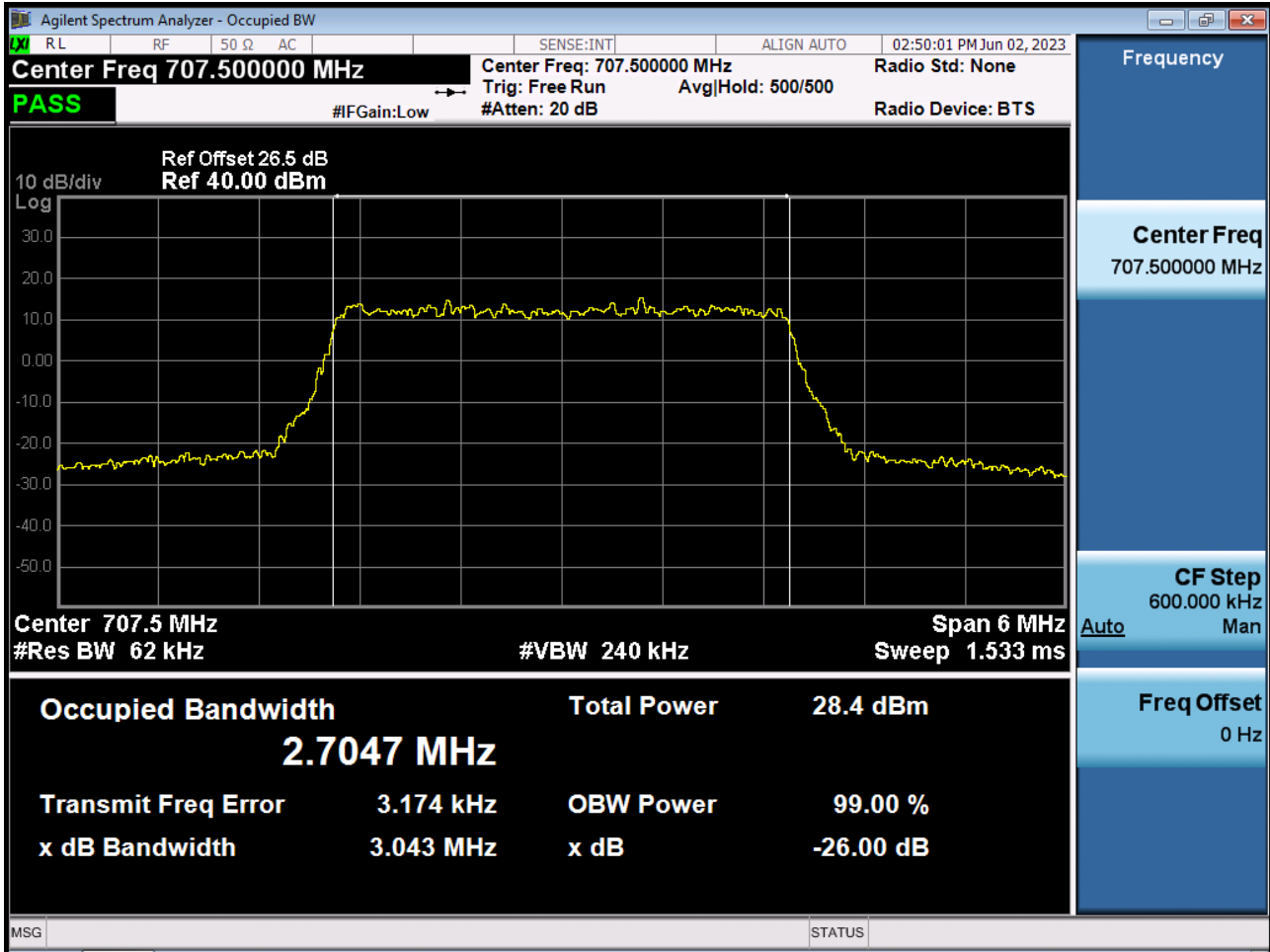
BAND 12. Occupied Bandwidth Plot (3 M BW Ch.23095 16QAM\_RB15\_0)



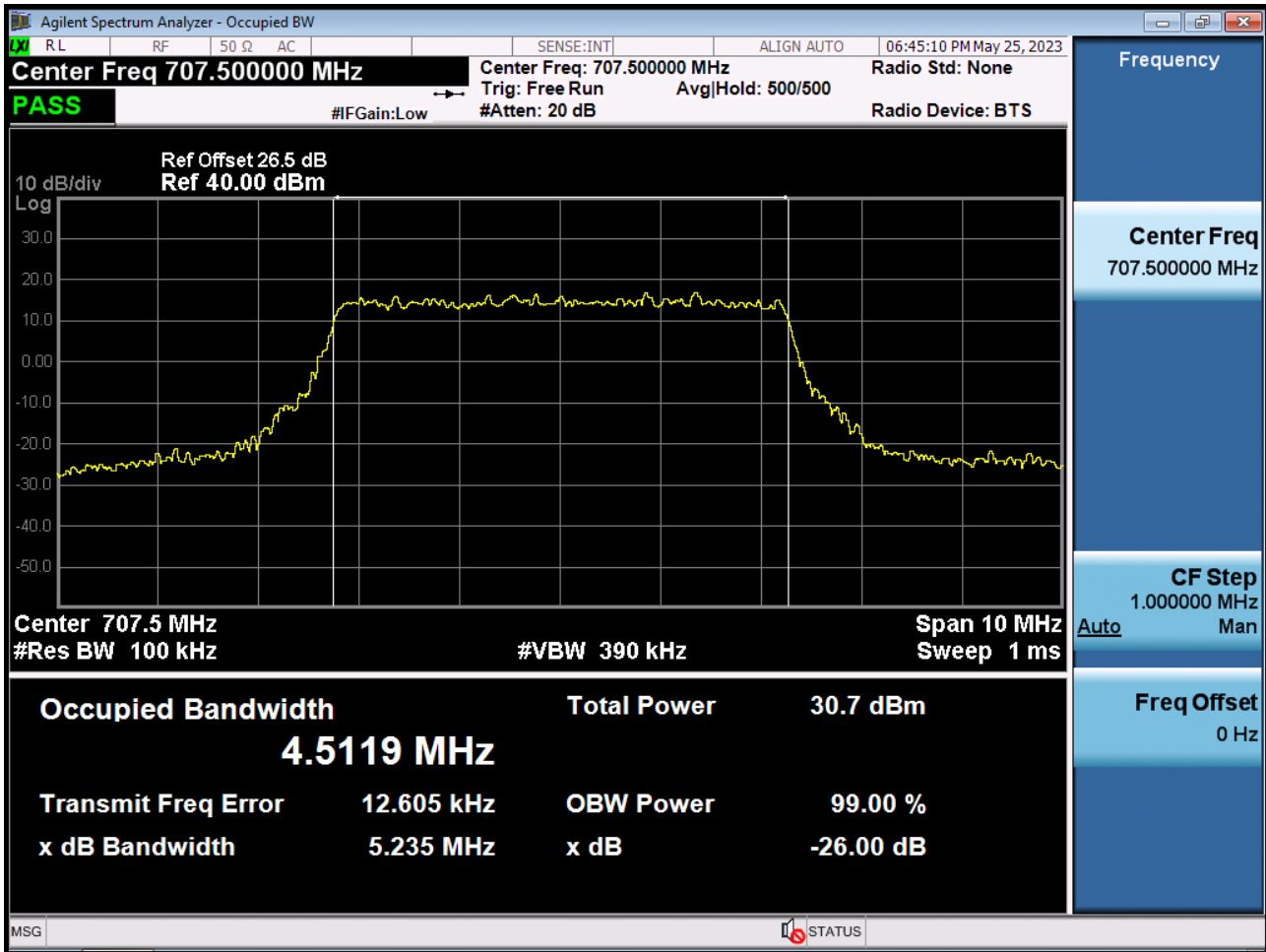
BAND 12. Occupied Bandwidth Plot (3 M BW Ch.23095 64QAM\_RB15\_0)



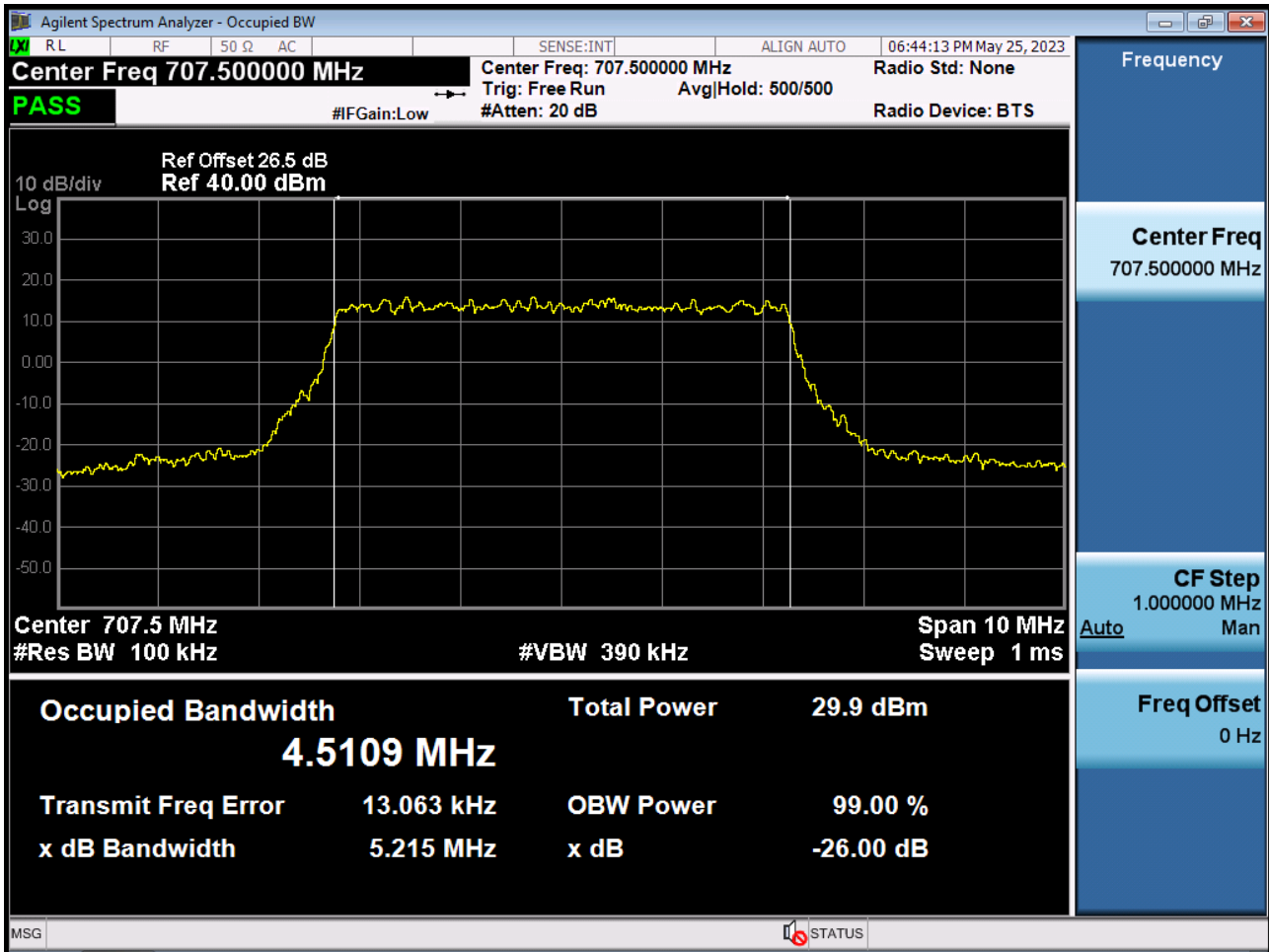
BAND 12. Occupied Bandwidth Plot (3 M BW Ch.23095 256QAM\_RB15\_0)



BAND 12. Occupied Bandwidth Plot (5 M BW Ch.23095 QPSK\_RB25\_0)

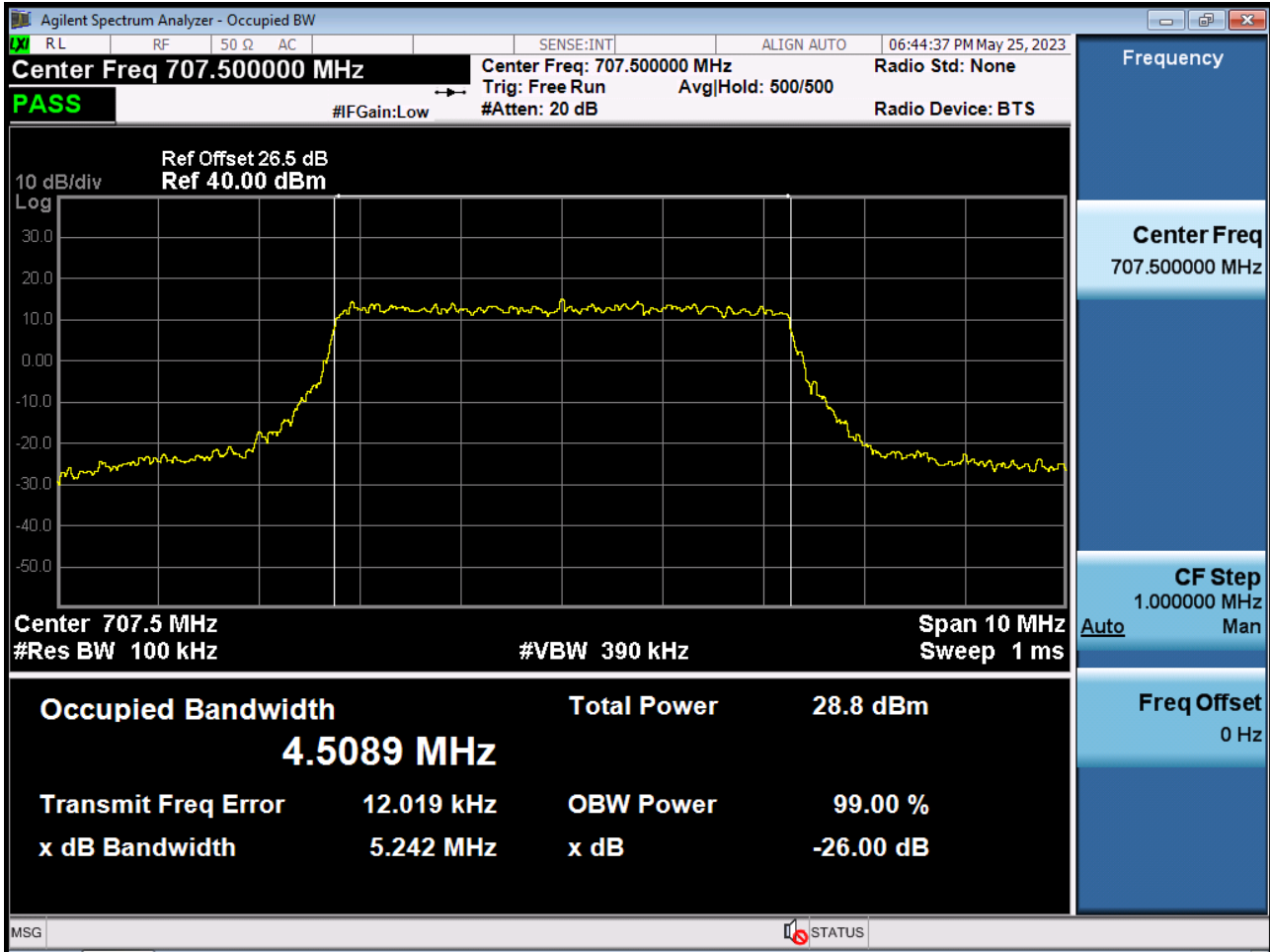


BAND 12. Occupied Bandwidth Plot (5 M BW Ch.23095 16QAM\_RB25\_0)

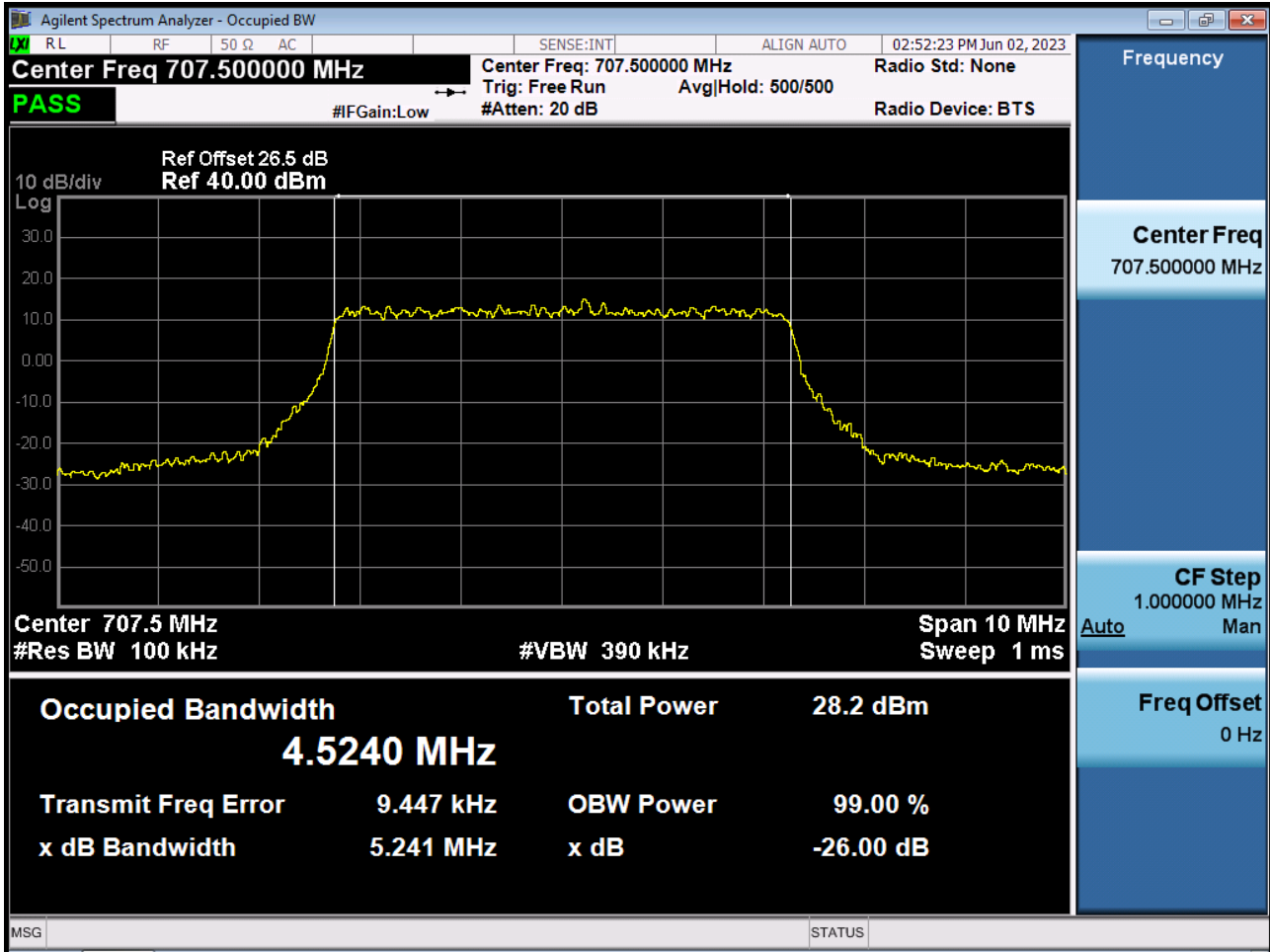




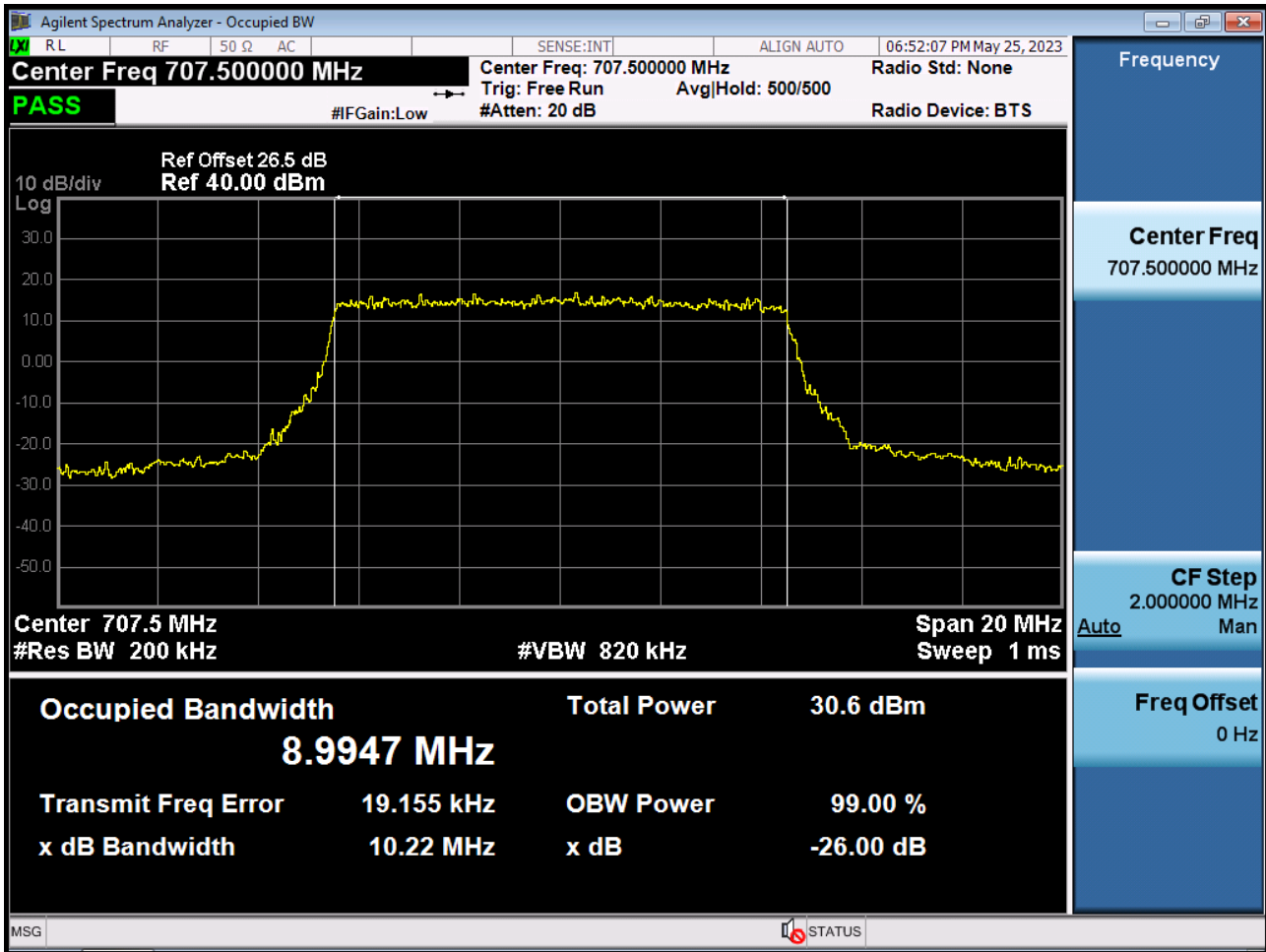
BAND 12. Occupied Bandwidth Plot (5 M BW Ch.23095 64QAM\_RB25\_0)



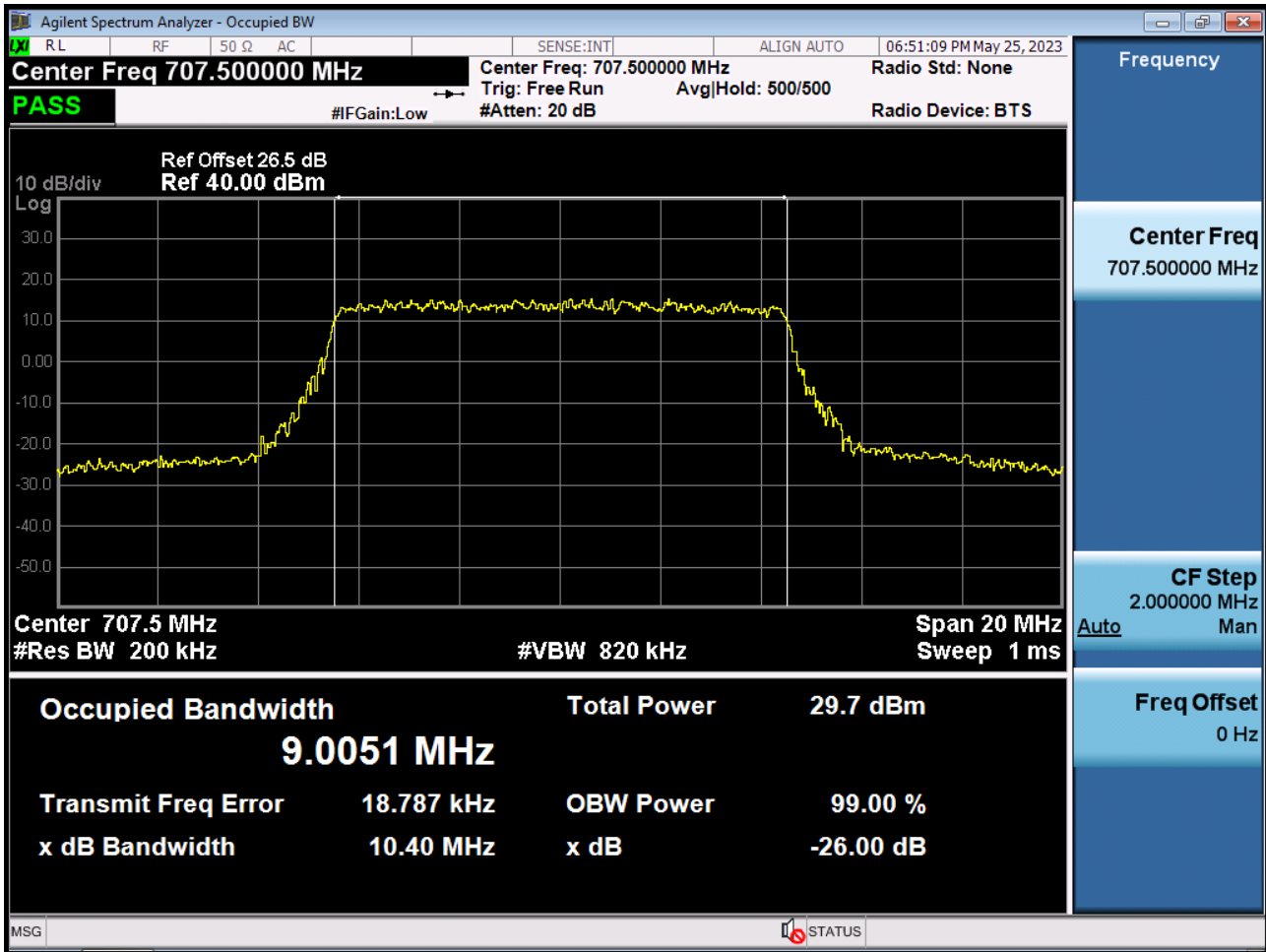
BAND 12. Occupied Bandwidth Plot (5 M BW Ch.23095 256QAM\_RB25\_0)



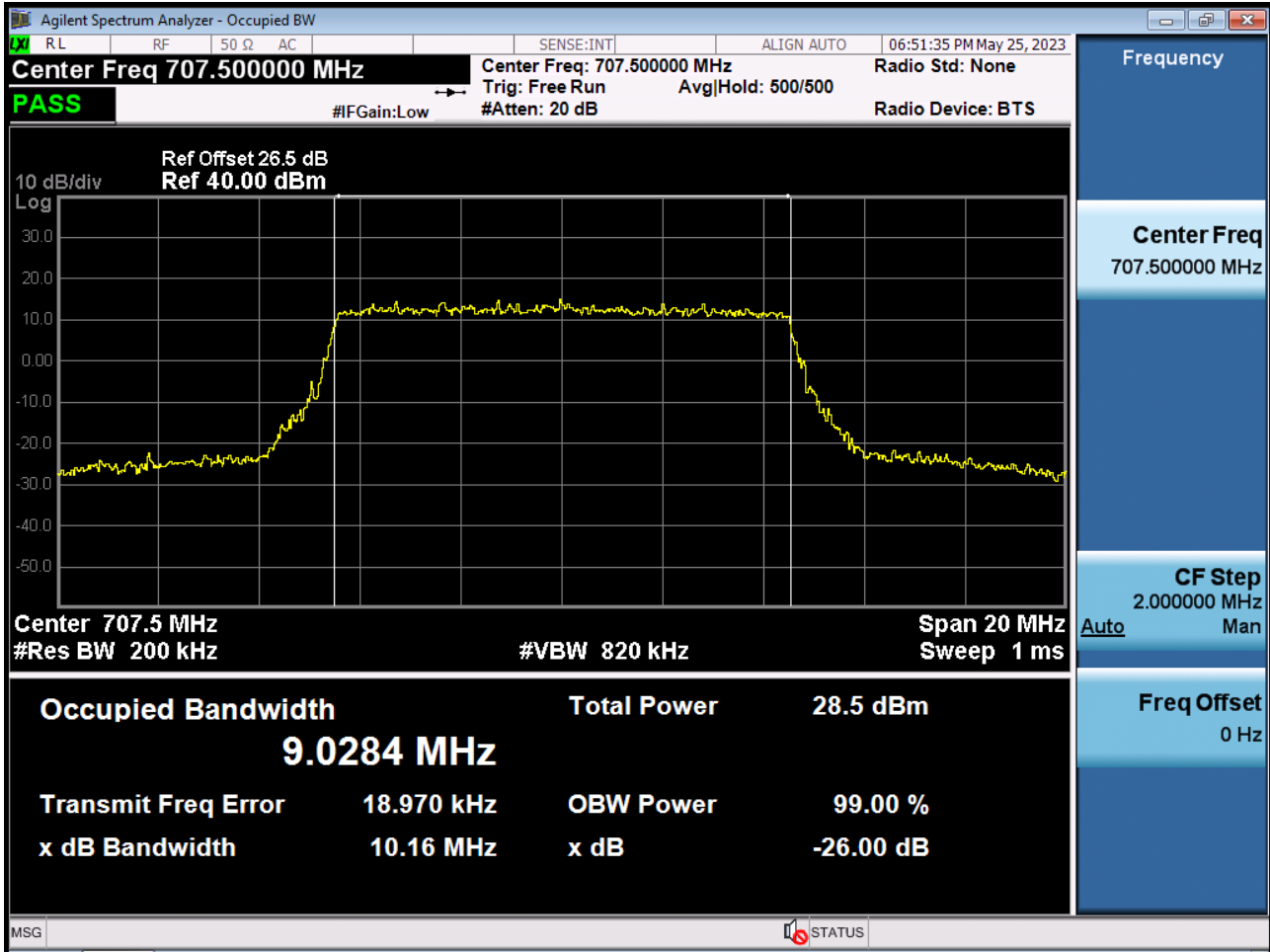
BAND 12. Occupied Bandwidth Plot (10 M BW Ch.23095 QPSK\_RB50\_0)



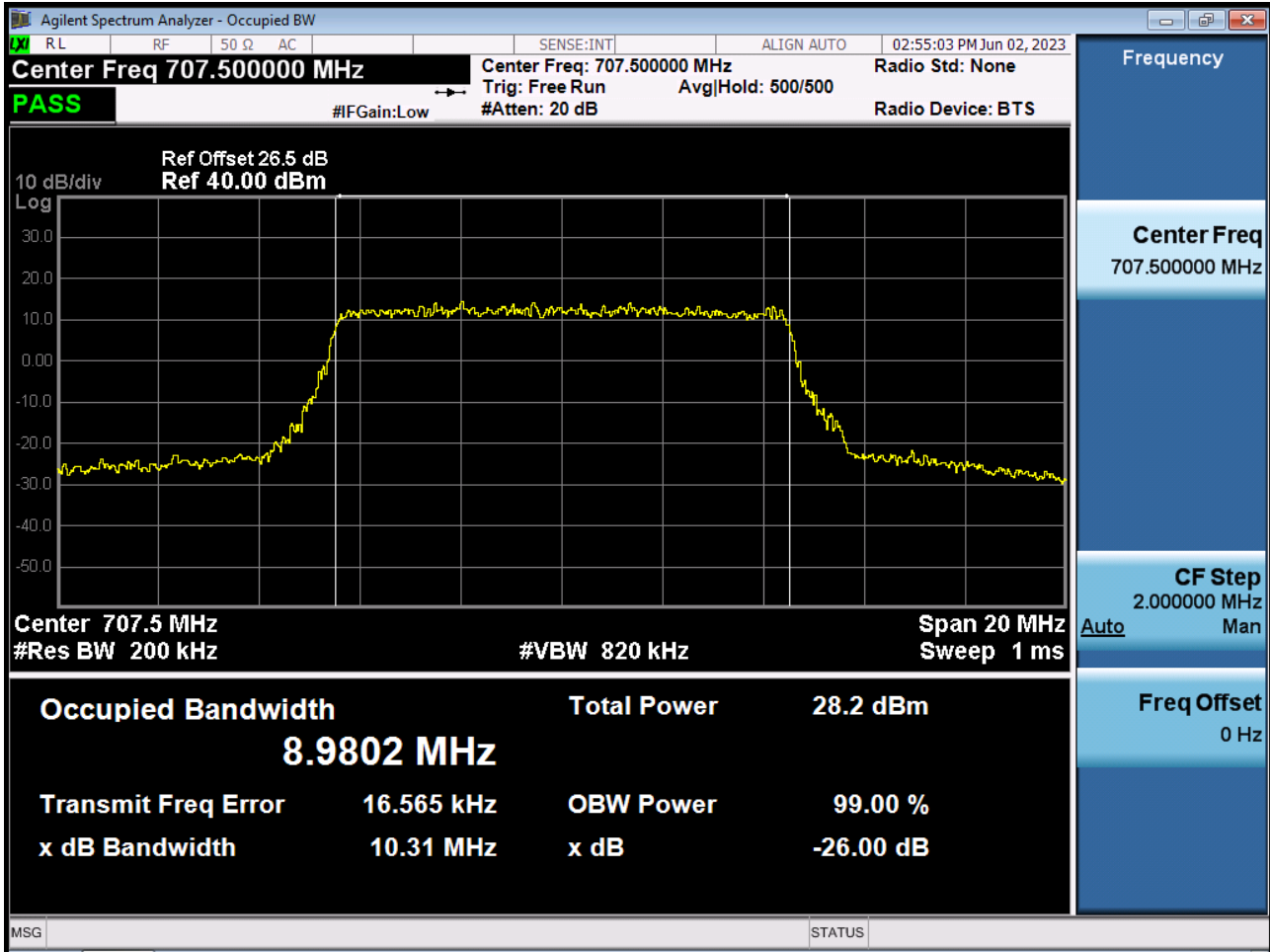
BAND 12. Occupied Bandwidth Plot (10 M BW Ch.23095 16QAM\_RB50\_0)



BAND 12. Occupied Bandwidth Plot (10 M BW Ch.23095 64QAM\_RB50\_0)



BAND 12. Occupied Bandwidth Plot (10 M BW Ch.23095 256QAM\_RB50\_0)





BAND 12. Lower Band Edge Plot (1.4 M BW Ch.23017 QPSK\_RB6\_Offset 0)





BAND 12. Lower Extended Band Edge Plot (1.4 M BW Ch.23017 QPSK\_RB6\_0)



BAND 12. Lower Band Edge Plot (3 M BW Ch.23025 QPSK\_RB1\_Offset 0)



BAND 12. Lower Band Edge Plot (3 M BW Ch.23025 QPSK\_RB15\_Offset 0)



BAND 12. Lower Extended Band Edge Plot (3 M BW Ch.23025 QPSK\_RB15\_0)



BAND 12. Lower Band Edge Plot (5 M BW Ch.23035 QPSK\_RB1\_Offset 0)



BAND 12. Lower Band Edge Plot (5 M BW Ch.23035 QPSK\_RB25\_Offset 0)



BAND 12. Lower Extended Band Edge Plot (5 M BW Ch.23035 QPSK\_RB25\_0)



BAND 12. Lower Band Edge Plot (10 M BW Ch.23060 QPSK\_RB1\_Offset 0)





BAND 12. Lower Band Edge Plot (10 M BW Ch.23060 QPSK\_RB50\_Offset 0)



BAND 12. Lower Extended Band Edge Plot (10 M BW Ch.23060 QPSK\_RB50\_0)



BAND 12. Upper Band Edge Plot (1.4 M BW Ch.23173 QPSK\_RB1\_Offset 5)\_1



BAND 12. Upper Band Edge Plot (1.4 M BW Ch.23173 QPSK\_RB1\_Offset 5)\_2





BAND 12. Upper Extended Band Edge Plot (1.4 M BW Ch.23173 QPSK\_RB6\_0)



BAND 12. Upper Band Edge Plot (3 M BW Ch.23165 QPSK\_RB1\_Offset 14)-1



BAND 12. Upper Band Edge Plot (3 M BW Ch.23165 QPSK\_RB1\_Offset 14)-2





BAND 12. Upper Band Edge Plot (3 M BW Ch.23165 QPSK\_RB15\_Offset 0)





BAND 12. Upper Band Edge Plot (5 M BW Ch.23155 QPSK\_RB1\_Offset 24)\_1



BAND 12. Upper Band Edge Plot (5 M BW Ch.23155 QPSK\_RB1\_Offset 24)\_2



BAND 12. Upper Band Edge Plot (5 M BW Ch.23155 QPSK\_RB25\_Offset 0)



BAND 12. Upper Extended Band Edge Plot (5 M BW Ch.23155 QPSK\_RB25\_0)



BAND 12. Upper Band Edge Plot (10 M BW Ch.23130 QPSK\_RB1\_Offset 49)\_1



BAND 12. Upper Band Edge Plot (10 M BW Ch.23130 QPSK\_RB1\_Offset 49)\_2





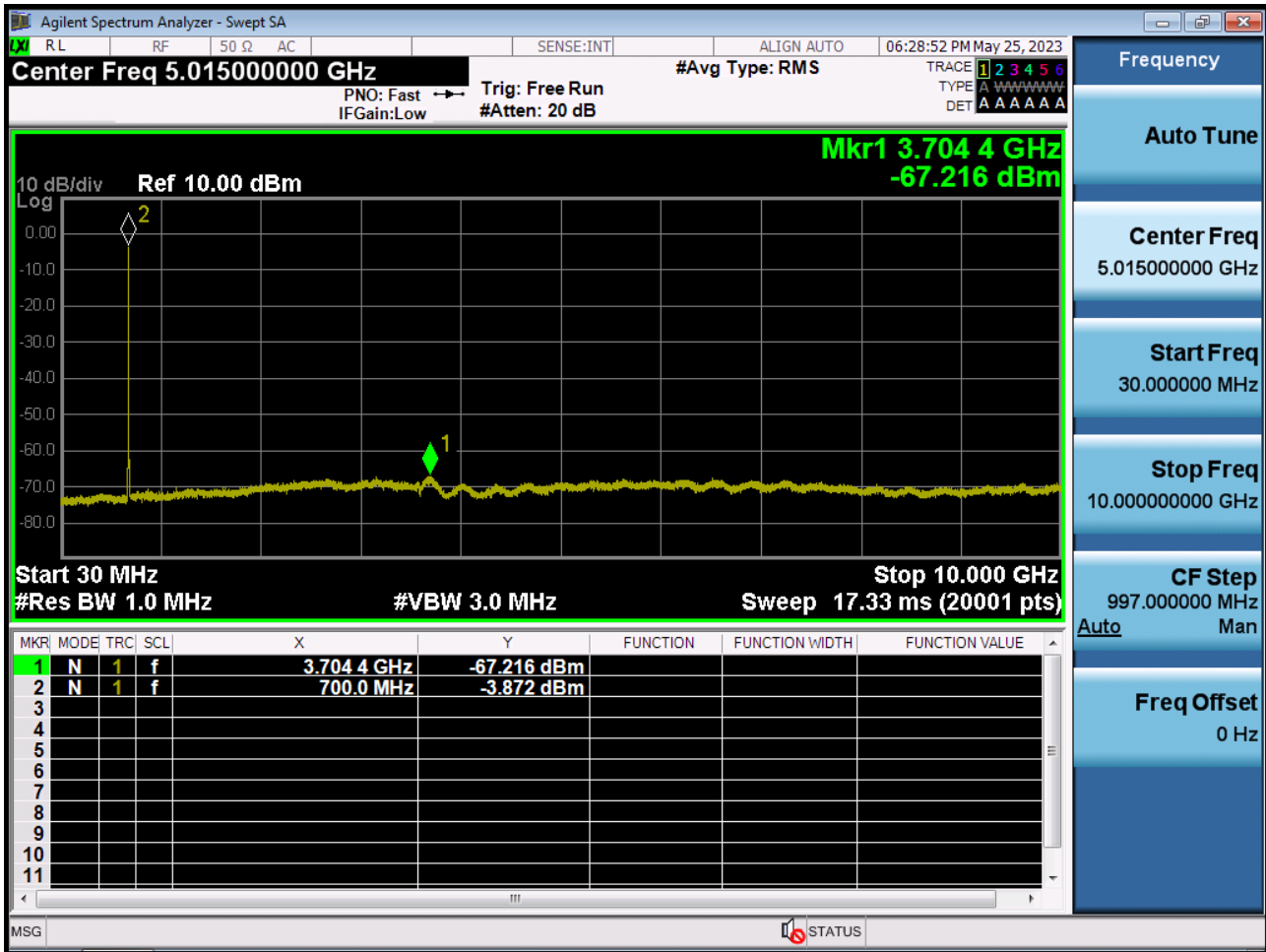
BAND 12. Upper Band Edge Plot (10 M BW Ch.23130 QPSK\_RB50\_Offset 0)



BAND 12. Upper Extended Band Edge Plot (10 M BW Ch.23130 QPSK\_RB50\_0)



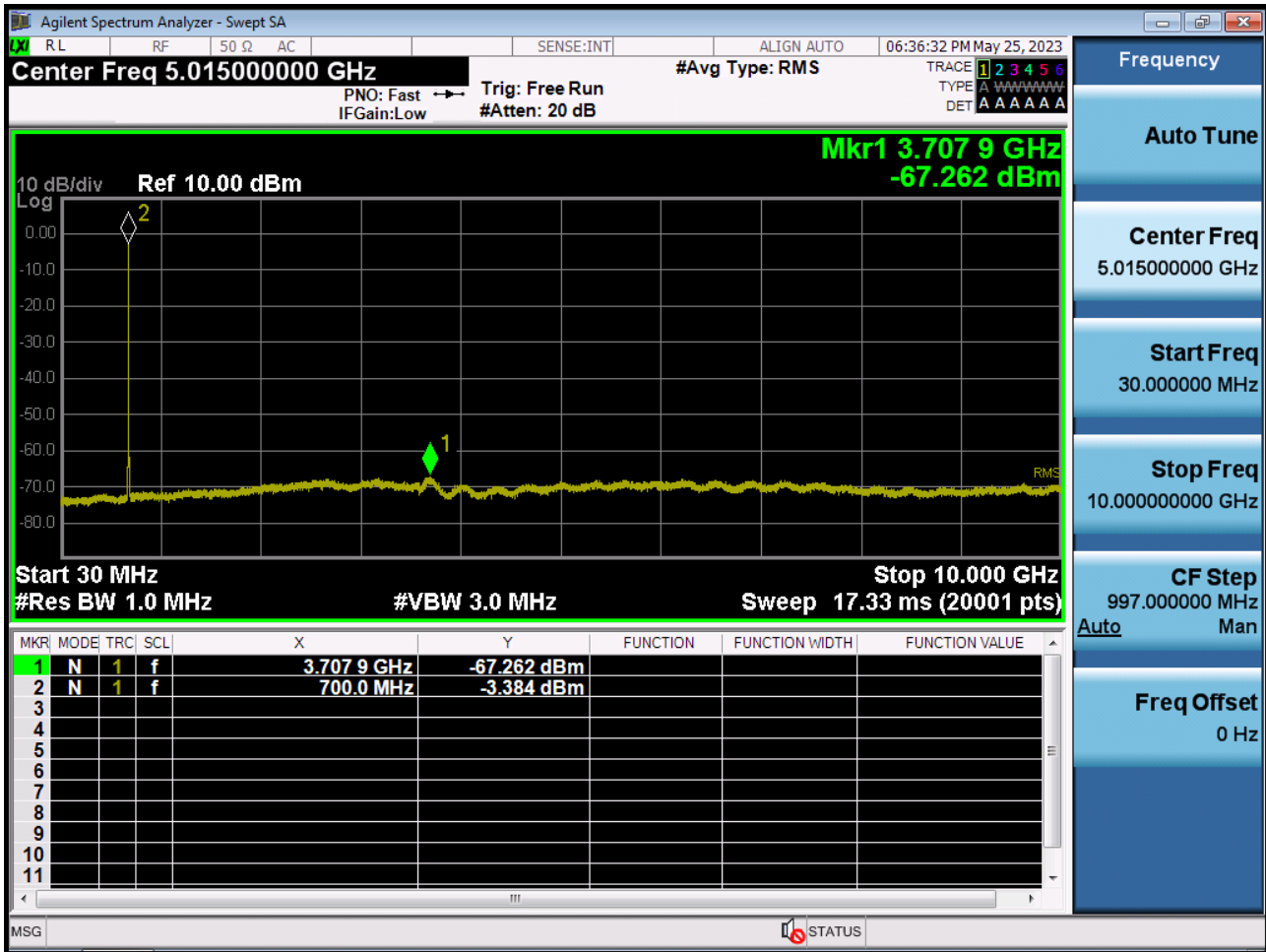
BAND 12. Conducted Spurious Plot \_ (23017ch\_1.4 MHz\_QPSK\_RB 1\_0)



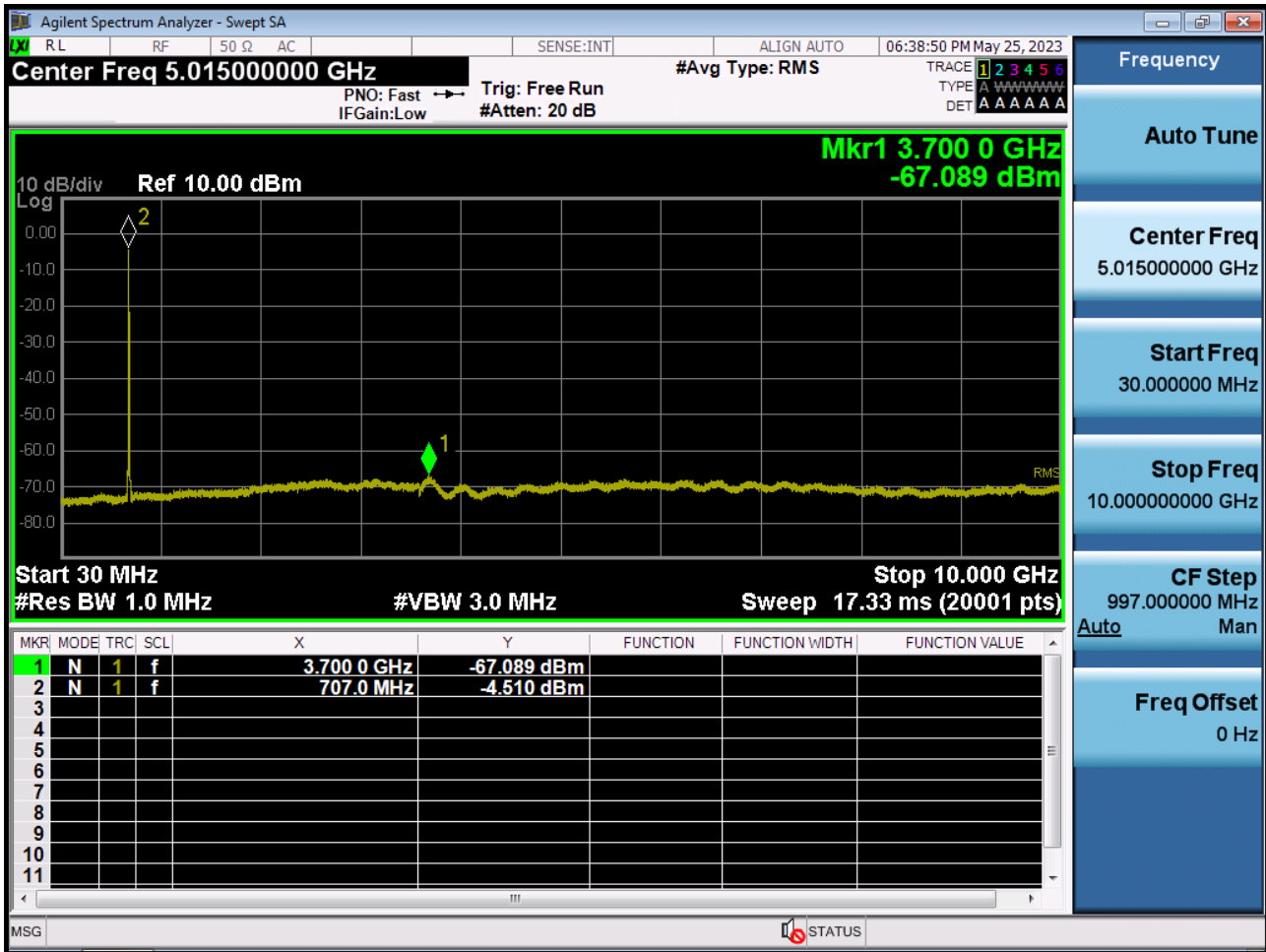




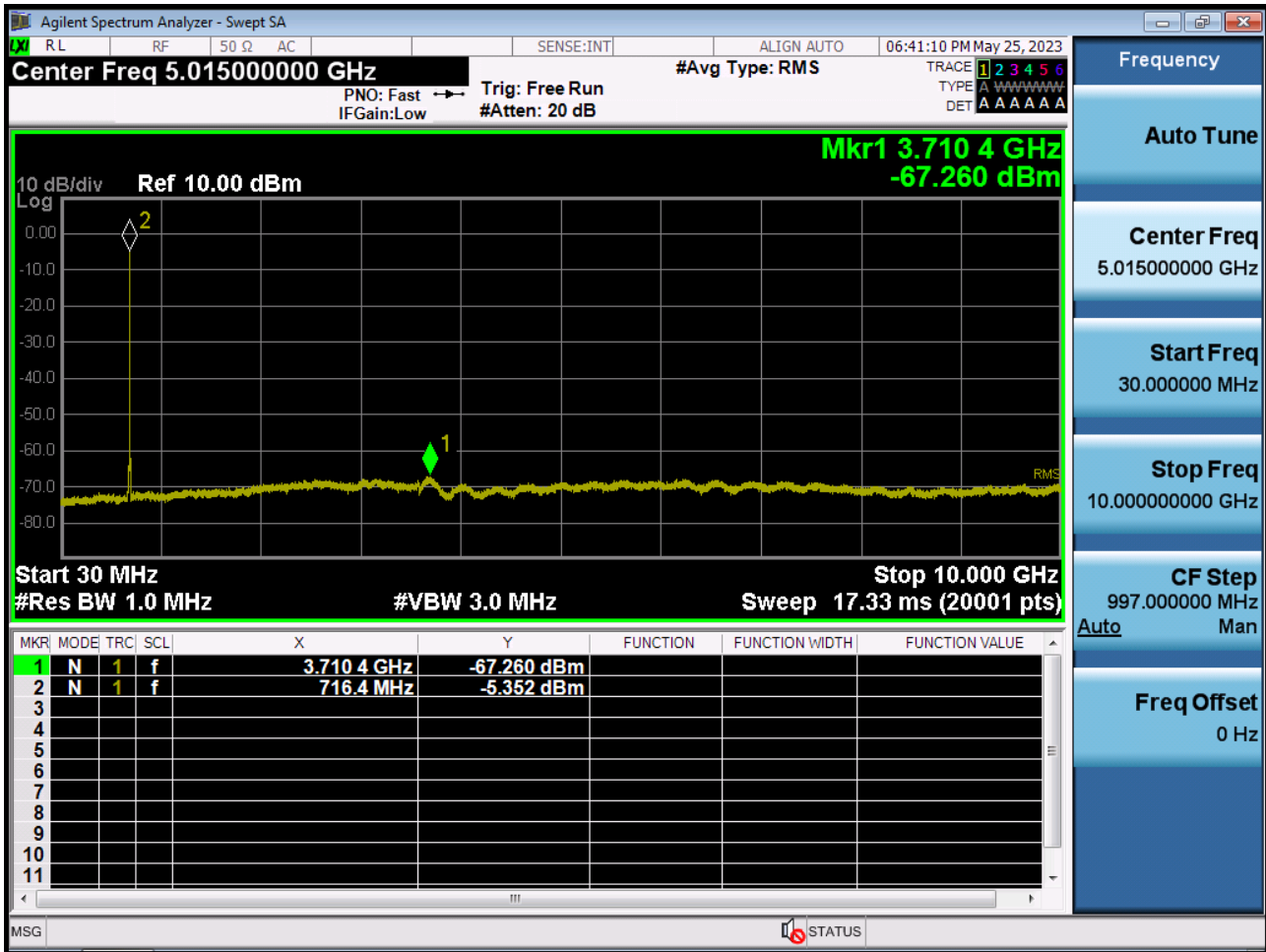
BAND 12. Conducted Spurious Plot \_ (23025ch\_3 MHz\_QPSK\_RB 1\_0)



BAND 12. Conducted Spurious Plot \_ (23095ch\_3 MHz\_QPSK\_RB 1\_0)

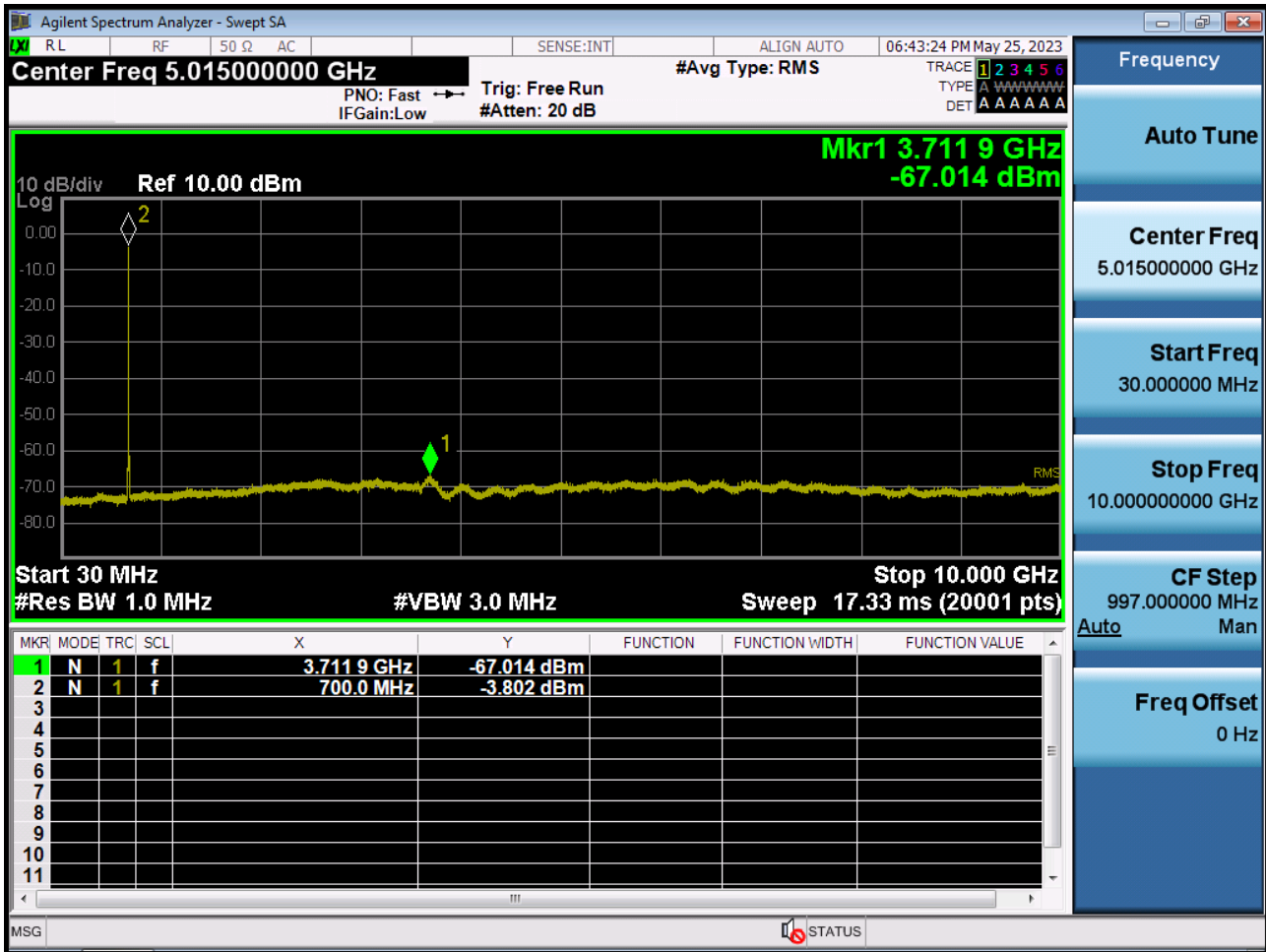


BAND 12. Conducted Spurious Plot \_ (23165ch\_3 MHz\_QPSK\_RB 1\_0)

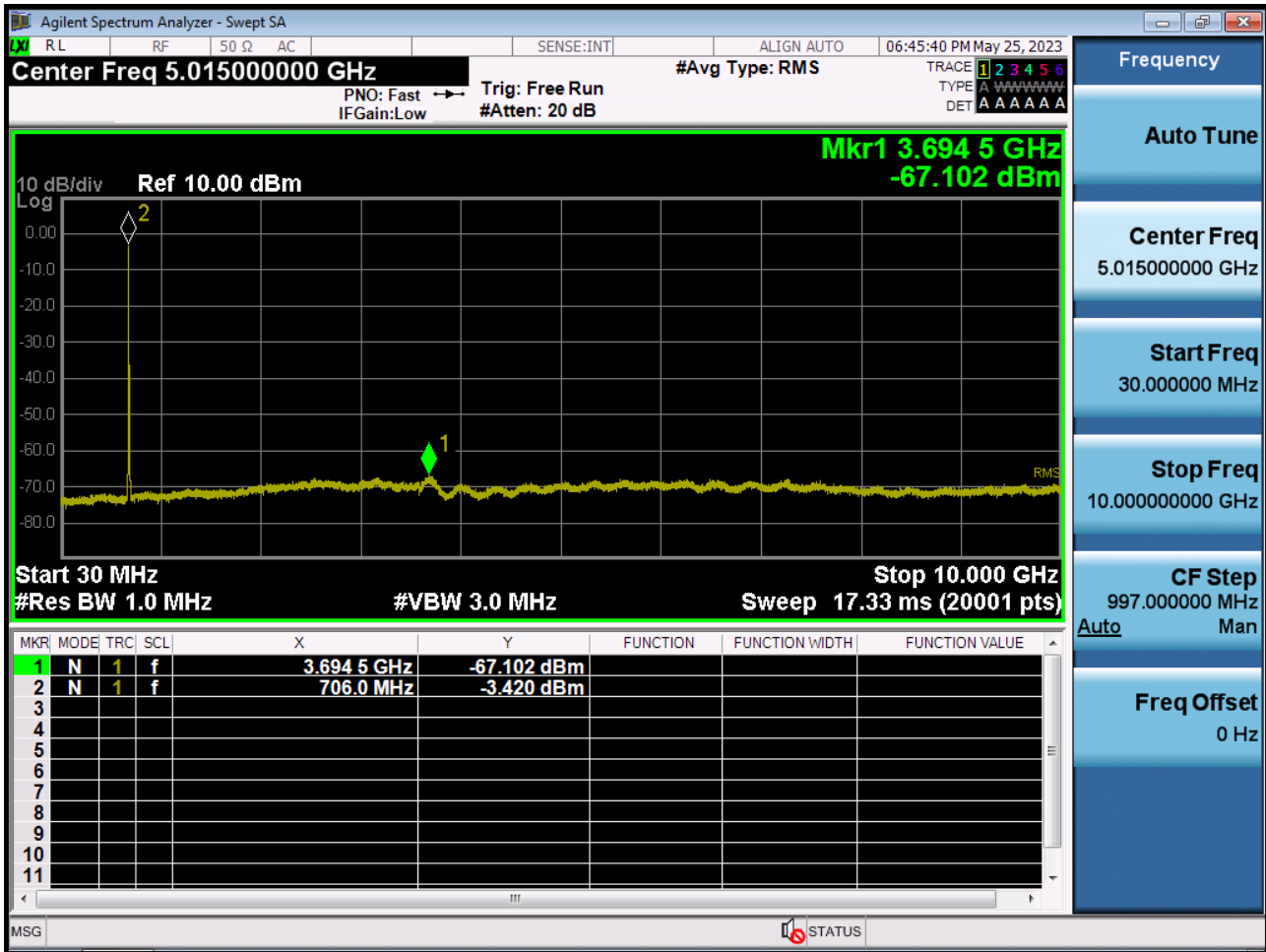




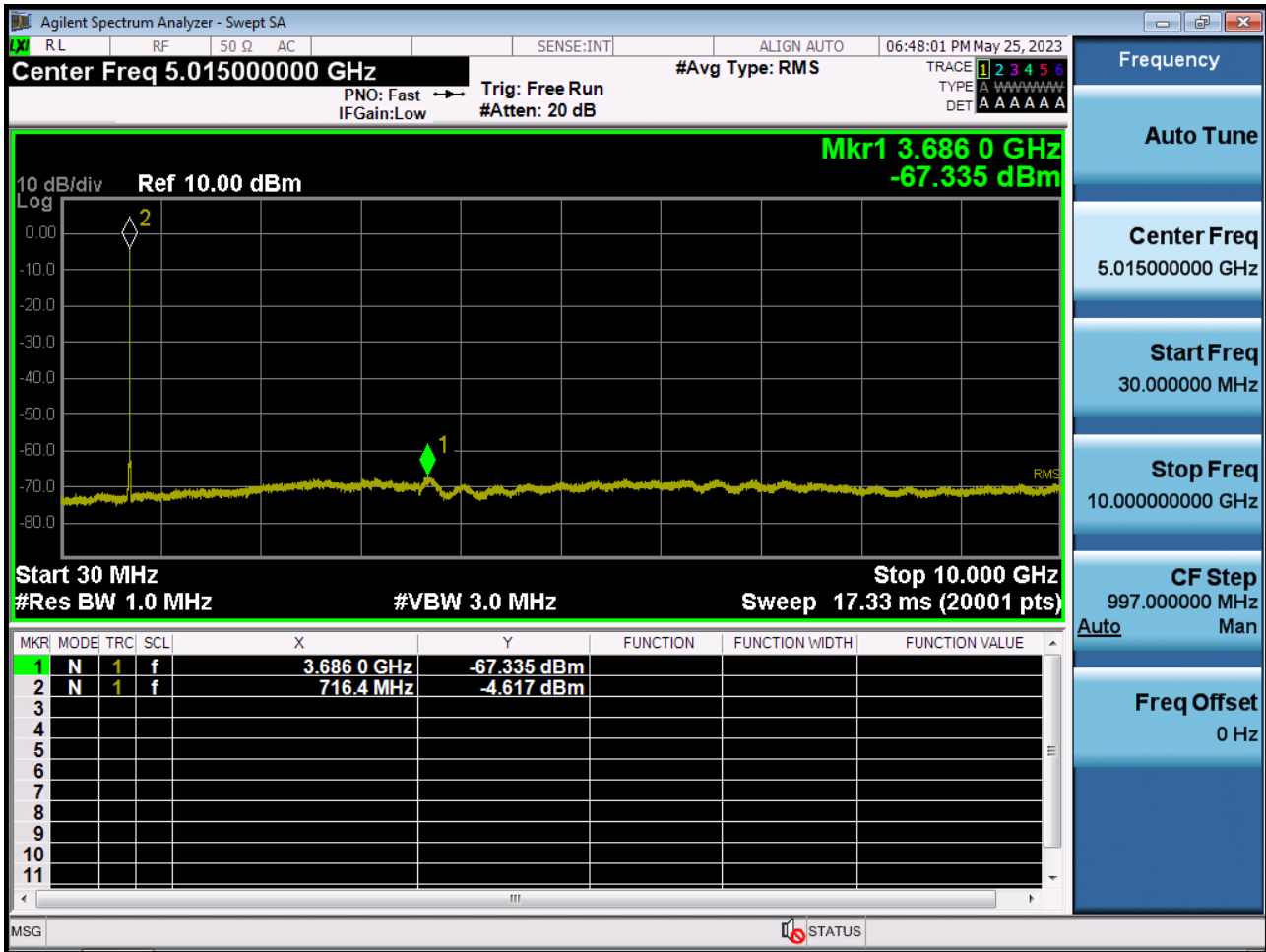
BAND 12. Conducted Spurious Plot \_ (23035ch\_5 MHz\_QPSK\_RB 1\_0)



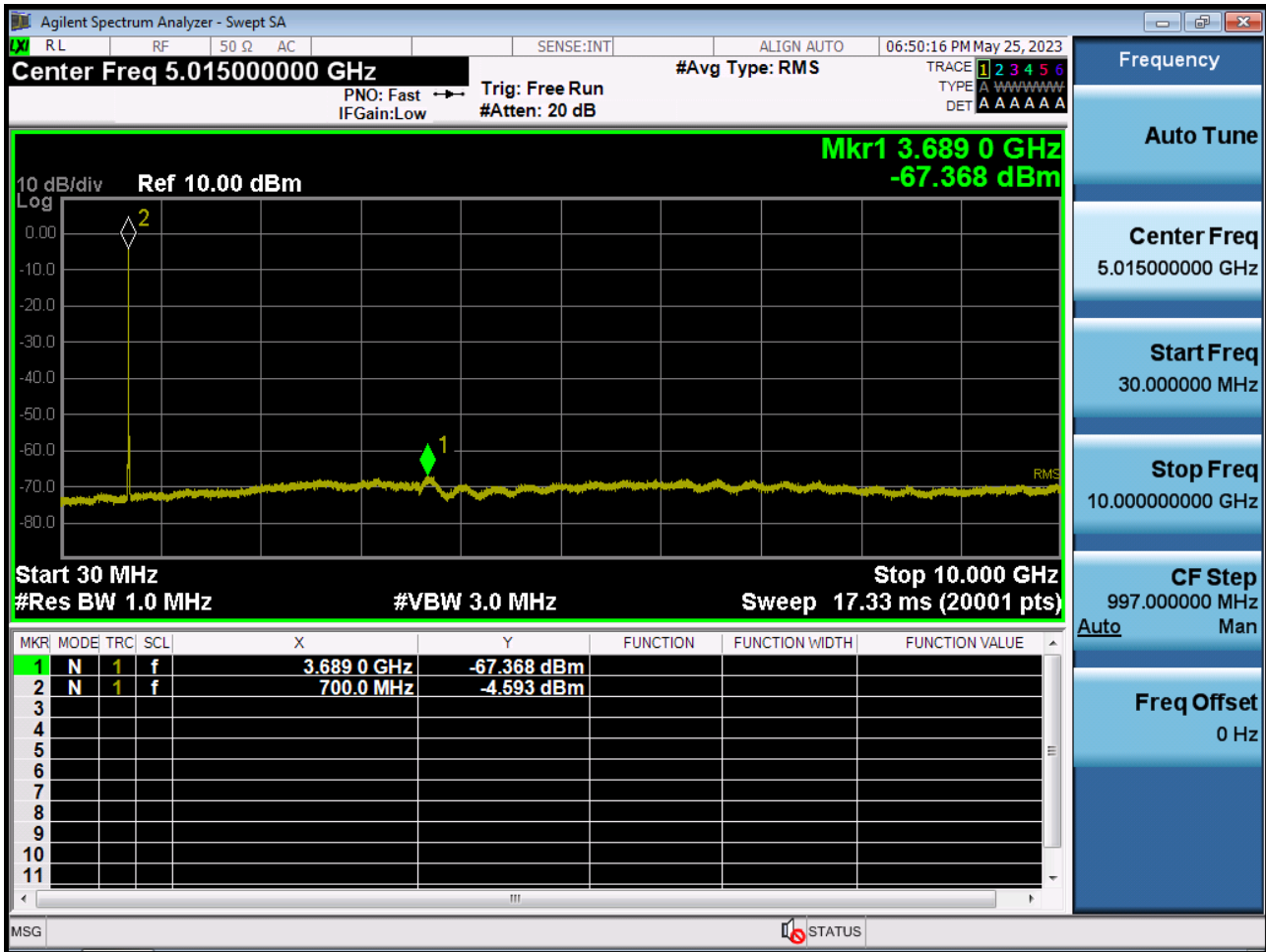
BAND 12. Conducted Spurious Plot \_ (23095ch\_5 MHz\_QPSK\_RB 1\_0)



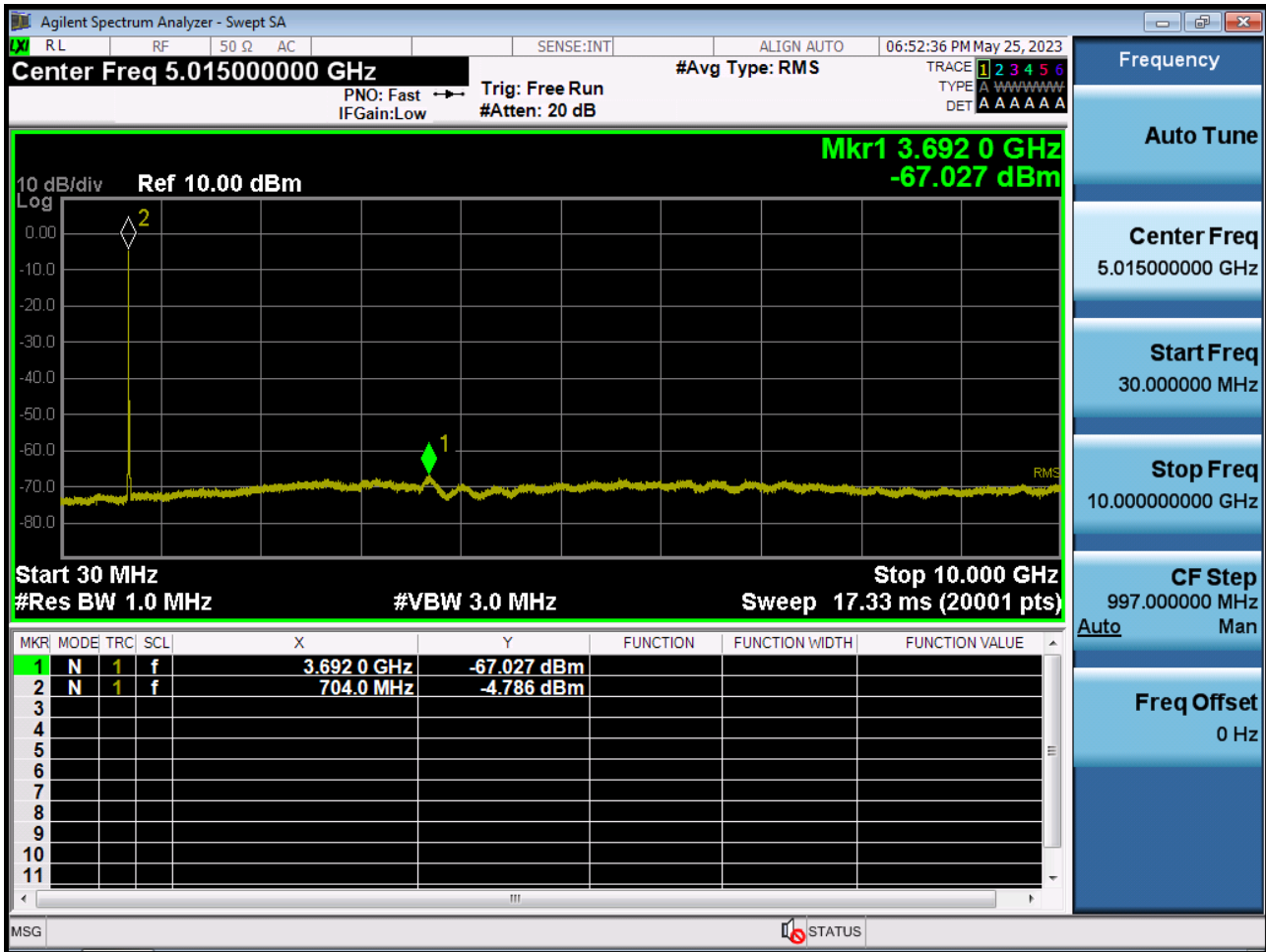
BAND 12. Conducted Spurious Plot \_ (23155ch\_5 MHz\_QPSK\_RB 1\_0)



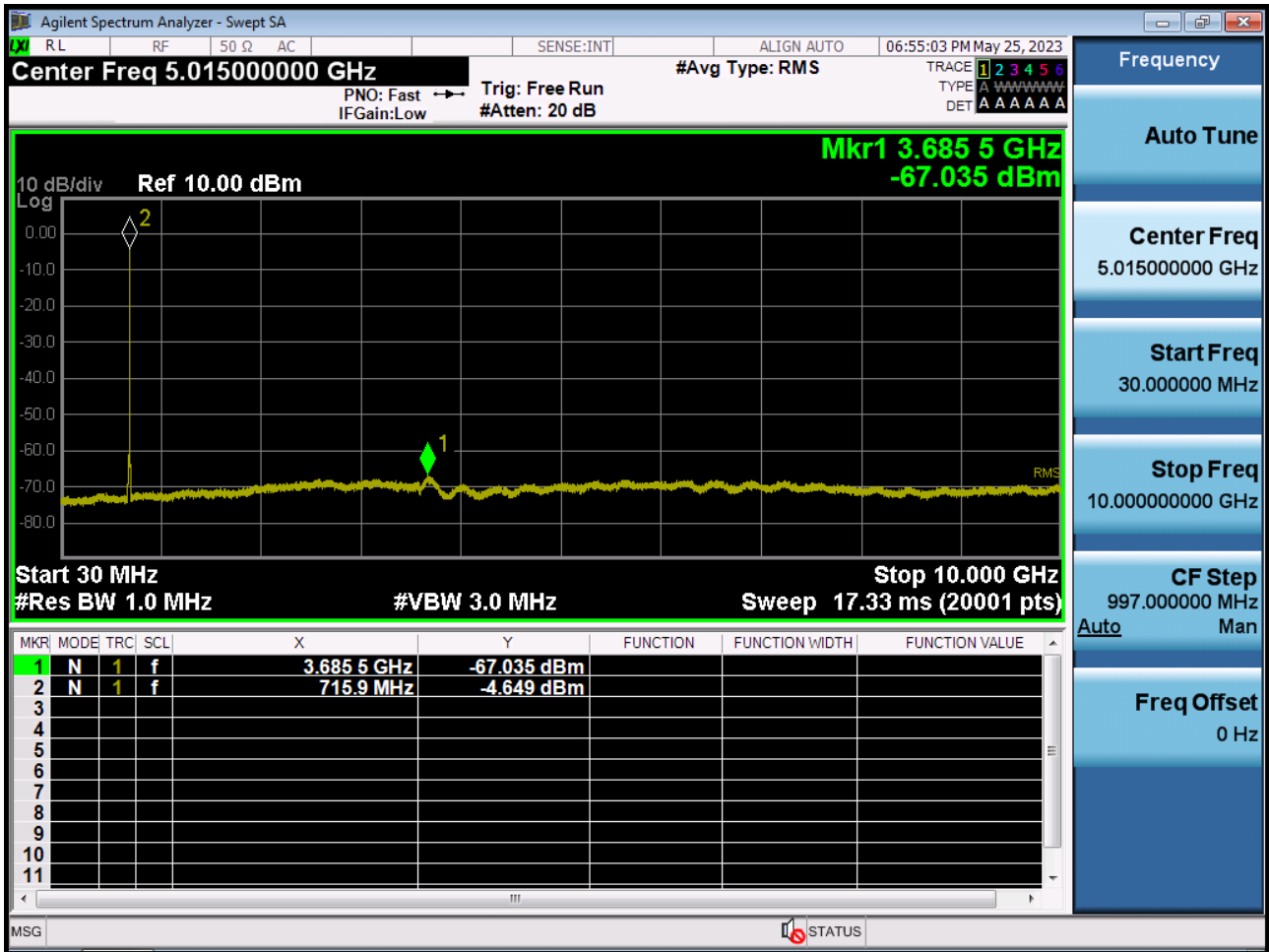
BAND 12. Conducted Spurious Plot \_ (23060ch\_10 MHz\_QPSK\_RB 1\_0)



BAND 12. Conducted Spurious Plot \_ (23095ch\_10 MHz\_QPSK\_RB 1\_0)



BAND 12. Conducted Spurious Plot \_ (23130ch\_10 MHz\_QPSK\_RB 1\_0)



## 10. ANNEX A\_ TEST SETUP PHOTO

Please refer to test setup photo file no. as follows;

No.	Description
1	HCT-RF-2309-FC019-P